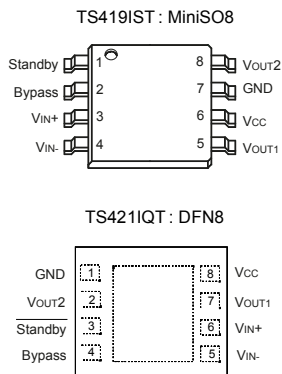


## 360 mW mono amplifier with standby mode



### Features

- Operating from  $V_{CC} = 2\text{ V}$  to  $5.5\text{ V}$
- Standby mode active high (TS419) or low (TS421)
- Output power into  $16\ \Omega$ :  $367\text{ mW @ }5\text{ V}$  with 10% THD+N max or  $295\text{ mW @ }5\text{ V}$  and  $110\text{ mW @ }3.3\text{ V}$  with 1% THD+N max.
- Low current consumption:  $2.5\text{ mA max.}$
- High signal-to-noise ratio:  $95\text{ dB (A)}$  at  $5\text{ V}$
- PSRR:  $56\text{ dB typ.}$  at  $1\text{ kHz}$ ,  $46\text{ dB}$  at  $217\text{ Hz}$
- Short-circuit limitation
- ON/OFF click reduction circuitry
- Available in MiniSO8 and DFN  $3\times 3$

### Applications

- $16/32\ \Omega$  earpiece or receiver speaker driver
- Mobile and cordless phones (analog / digital)
- PDAs & computers
- Portable appliances

### Description

The TS419/TS421 is a monaural audio power amplifier driving in BTL mode a  $16$  or  $32\ \Omega$  earpiece or receiver speaker. The main advantage of this configuration is to get rid of bulky output capacitors.

Capable of descending to low voltages, it delivers up to  $220\text{ mW}$  per channel (into  $16\ \Omega$  loads) of continuous average power with 0.2% THD+N in the audio bandwidth from a  $5\text{ V}$  power supply.

An externally controlled standby mode reduces the supply current to  $10\text{ nA (typ.)}$ . The TS419 / TS421 can be configured by external gain-setting resistors.

Maturity status link

[TS3431](#)

# 1 Maximum ratings

**Table 1. Absolute maximum ratings**

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply voltage <sup>(1)</sup>	6	V
$V_i$	Input voltage	-0.3 V to $V_{CC} + 0.3$ V	V
$T_{stg}$	Storage temperature	-65 to +150	°C
$T_j$	Maximum junction temperature	150	°C
$R_{thja}$	Thermal resistance junction-to-ambient		
	MiniSO8	215	°C/W
DFN8	70		
$P_d$	Power dissipation <sup>(2)</sup>		
	MiniSO8	0.58	W
	DFN8	1.79	
ESD	Human body model (pin to pin): TS419 <sup>(3)</sup> , TS421	1.5	kV
ESD	Machine Model - 220 pF - 240 pF (pin to pin)	100	V
Latch-up	Latch-up Immunity (All pins)	200	mA
	Lead temperature (soldering, 10 s)	250	°C
	Output short-circuit to $V_{CC}$ or GND	continuous <sup>(4)</sup>	

1. All voltage values are measured with respect to the ground pin.
2.  $P_d$  has been calculated with  $T_{amb} = 25$  °C,  $T_j = 150$  °C.
3. TS419 stands 1.5 KV on all pins except standby pin which stands 1 KV
4. Attention must be paid to continuous power dissipation ( $V_{DD} \times 300$  mA). Exposure of the IC to a short circuit for an extended time period is dramatically reducing product life expectancy.

**Table 2. Operating conditions**

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply voltage	2 to 5.5	V
$R_L$	Load resistor	$\geq 16$	$\Omega$
$T_{oper}$	Operating free air temperature range	-40 to +85	°C
$C_L$	Load capacitor		
	$R_L = 16$ to $100$ $\Omega$	400	pF
	$R_L > 100$ $\Omega$	100	
$V_{ICM}$	Common mode input voltage range	GND to $V_{CC} - 1$ V	V
$V_{STB}$	Standby voltage input	$1.5 \leq V_{STB} \leq V_{CC}$	V
	TS421 ACTIVE / TS419 in STANDBY TS421 in STANDBY / TS419 ACTIVE	GND $\leq V_{STB} \leq 0.4$ <sup>(1)</sup>	
$R_{thja}$	Thermal resistance junction-to-ambient		
	MiniSO8	190	°C/W
	DFN8 <sup>(2)</sup>	41	

Symbol	Parameter	Value	Unit
$T_{WU}$	Wake-up time from standby to active mode ( $C_b = 1 \mu F$ ) <sup>(3)</sup>	$\geq 0.12$	s

1. The minimum current consumption ( $I_{STANDBY}$ ) is guaranteed at  $V_{CC}$  (TS419) or GND (TS421) for the whole temperature range.
2. When mounted on a 4-layer PCB.
3. For more details on  $T_{WU}$ , please refer to application note section on Wake-up time page 28.

## 2 Typical application schematics

Figure 1. Application schematics

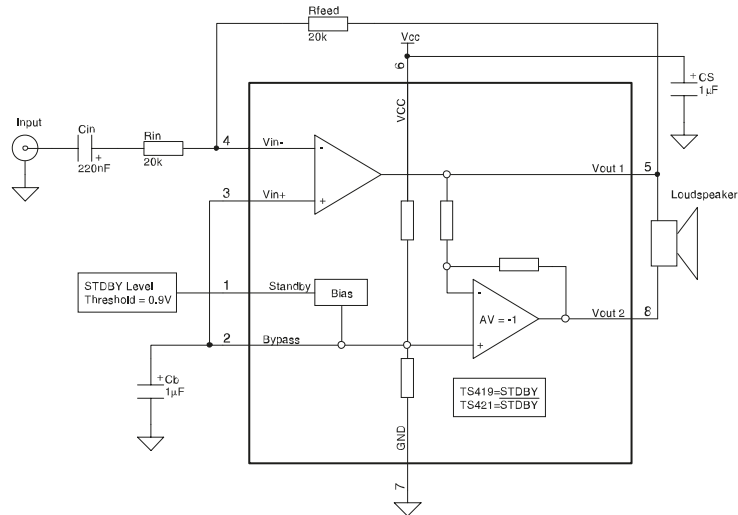


Table 3. Application components information

Components	Functional description
$R_{IN}$	Inverting input resistor which sets the closed loop gain in conjunction with $R_{FEED}$ . This resistor also forms a high pass filter with $C_{IN}$ ( $f_{cl} = 1 / (2 \times P_i \times R_{IN} \times C_{IN})$ ).
$C_{IN}$	Input coupling capacitor which blocks the DC voltage at the amplifier's input terminal.
$R_{FEED}$	Feedback resistor which sets the closed loop gain in conjunction with $R_{IN}$ . $A_V = \text{Closed Loop Gain} = 2 \times R_{FEED} / R_{IN}$ .
$C_S$	Supply bypass capacitor which provides power supply filtering.
$C_B$	Bypass capacitor which provides half supply filtering.

### 3 Electrical characteristics

**Table 4. Electrical characteristics  $V_{CC} = +5\text{ V}$ ,  $GND = 0\text{ V}$ ,  $T_{amb} = 25\text{ °C}$  (unless otherwise specified)**

Symbol	Parameter	Min.	Typ.	Max.	Unit
$I_{CC}$	Supply current No input signal, no load		6	8	mA
$I_{STANDBY}$	Standby current No input signal, $V_{STANDBY} = GND$ for TS421 No input signal, $V_{STANDBY} = V_{CC}$ for TS419		10	1000	nA
$V_{OO}$	Output offset voltage No input signal, $R_L = 16\ \Omega$ or $32\ \Omega$ , $R_{feed} = 20\text{ k}\Omega$		5	25	mV
$P_O$	Output power THD+N = 0.1% Max, $F = 1\text{ kHz}$ , $R_L = 32\ \Omega$		190		mW
	Output power THD+N = 1% Max, $F = 1\text{ kHz}$ , $R_L = 32\ \Omega$	166	207		
	Output power THD+N = 10% Max, $F = 1\text{ kHz}$ , $R_L = 32\ \Omega$		258		
	Output power THD+N = 0.1% Max, $F = 1\text{ kHz}$ , $R_L = 16\ \Omega$		270		
	Output power THD+N = 1% Max, $F = 1\text{ kHz}$ , $R_L = 16\ \Omega$	240	295		
	Output power THD+N = 10% Max, $F = 1\text{ kHz}$ , $R_L = 16\ \Omega$		367		
THD + N	Total harmonic distortion + noise ( $A_v = 2$ ) $R_L = 32\ \Omega$ , $P_{out} = 150\text{ mW}$ , $20\text{ Hz} \leq F \leq 20\text{ kHz}$ $R_L = 16\ \Omega$ , $P_{out} = 220\text{ mW}$ , $20\text{ Hz} \leq F \leq 20\text{ kHz}$		0.15 0.2		%
PSRR	Power supply rejection ratio ( $A_v = 2$ ) $F = 1\text{ kHz}$ , $V_{ripple} = 200\text{ mVpp}$ , input grounded, $C_b = 1\ \mu\text{F}$	50	56		dB
SNR	Signal-to-Noise Ratio (Filter Type A, $A_v = 2$ ) <sup>(1)</sup> ( $R_L = 32\ \Omega$ , THD + N < 0.5%, $20\text{ Hz} \leq F \leq 20\text{ kHz}$ )	85	98		dB
$\phi_M$	Phase margin at unity gain $R_L = 16\ \Omega$ , $C_L = 400\text{ pF}$		58		Degrees
GM	Gain margin $R_L = 16\ \Omega$ , $C_L = 400\text{ pF}$		18		dB
GBP	Gain bandwidth product $R_L = 16\ \Omega$		1.1		MHz
SR	Slew rate $R_L = 16\ \Omega$		0.4		V/ $\mu\text{S}$

1. Guaranteed by design and evaluation.

**Table 5. Electrical characteristics  $V_{CC} = +3.3\text{ V}$ ,  $GND = 0\text{ V}$ ,  $T_{amb} = 25\text{ °C}$  (unless otherwise specified)**

Symbol	Parameter	Min.	Typ.	Max.	Unit
$I_{CC}$	Supply current No input signal, no load		1.8	2.5	mA
$I_{STANDBY}$	Standby current No input signal, $V_{STANDBY} = GND$ for TS421 No input signal, $V_{STANDBY} = V_{CC}$ for TS419		10	1000	nA
$V_{OO}$	Output offset voltage No input signal, $R_L = 16\ \Omega$ or $32\ \Omega$ , $R_{feed} = 20\text{ k}\Omega$		5	25	mV
$P_O$	Output power THD+N = 0.1% Max, $F = 1\text{ kHz}$ , $R_L = 32\ \Omega$		75		mW
	Output power THD+N = 1% Max, $F = 1\text{ kHz}$ , $R_L = 32\ \Omega$	65	81		
	Output power THD+N = 10% Max, $F = 1\text{ kHz}$ , $R_L = 32\ \Omega$		102		
	Output power THD+N = 0.1% Max, $F = 1\text{ kHz}$ , $R_L = 16\ \Omega$		104		
	Output power THD+N = 1% Max, $F = 1\text{ kHz}$ , $R_L = 16\ \Omega$	91	113		
	Output power THD+N = 10% Max, $F = 1\text{ kHz}$ , $R_L = 16\ \Omega$		143		
THD + N	Total harmonic distortion + noise ( $A_v = 2$ ) $R_L = 32\ \Omega$ , $P_{out} = 150\text{ mW}$ , $20\text{ Hz} \leq F \leq 20\text{ kHz}$ $R_L = 16\ \Omega$ , $P_{out} = 220\text{ mW}$ , $20\text{ Hz} \leq F \leq 20\text{ kHz}$		0.15 0.2		%
PSRR	Power supply rejection ratio ( $A_v = 2$ ) $F = 1\text{ kHz}$ , $V_{ripple} = 200\text{ mVpp}$ , input grounded, $C_b = 1\ \mu\text{F}$	50	56		dB
SNR	Signal-to-Noise Ratio (Weighted A, $A_v = 2$ ) ( $R_L = 32\ \Omega$ , THD + N < 0.5%, $20\text{ Hz} \leq F \leq 20\text{ kHz}$ )	82	94		dB
$\phi_M$	Phase margin at unity gain $R_L = 16\ \Omega$ , $C_L = 400\text{ pF}$		58		Degrees
GM	Gain margin $R_L = 16\ \Omega$ , $C_L = 400\text{ pF}$		18		dB
GBP	Gain bandwidth product $R_L = 16\ \Omega$		1.1		MHz
SR	Slew rate $R_L = 16\ \Omega$		0.4		V/ $\mu\text{S}$

Note: All electrical values are guaranteed with correlation measurements at 2 V and 5 V.

**Table 6. Electrical characteristics  $V_{CC} = +2.5\text{ V}$ ,  $GND = 0\text{ V}$ ,  $T_{amb} = 25\text{ °C}$  (unless otherwise specified)**

Symbol	Parameter	Min.	Typ.	Max.	Unit
$I_{CC}$	Supply current No input signal, no load		1.7	2.5	mA
$I_{STANDBY}$	Standby current No input signal, $V_{STANDBY} = GND$ for TS421 No input signal, $V_{STANDBY} = V_{CC}$ for TS419		10	1000	nA
$V_{OO}$	Output offset voltage No input signal, $R_L = 16\ \Omega$ or $32\ \Omega$ , $R_{feed} = 20\text{ k}\Omega$		5	25	mV
$P_O$	Output power THD+N = 0.1% Max, $F = 1\text{ kHz}$ , $R_L = 32\ \Omega$		37		mW
	Output power THD+N = 1% Max, $F = 1\text{ kHz}$ , $R_L = 32\ \Omega$	32	41		
	Output power THD+N = 10% Max, $F = 1\text{ kHz}$ , $R_L = 32\ \Omega$		52		
	Output power THD+N = 0.1% Max, $F = 1\text{ kHz}$ , $R_L = 16\ \Omega$		50		
	Output power THD+N = 1% Max, $F = 1\text{ kHz}$ , $R_L = 16\ \Omega$	44	55		
	Output power THD+N = 10% Max, $F = 1\text{ kHz}$ , $R_L = 16\ \Omega$		70		
THD + N	Total harmonic distortion + noise ( $A_v = 2$ ) $R_L = 32\ \Omega$ , $P_{out} = 150\text{ mW}$ , $20\text{ Hz} \leq F \leq 20\text{ kHz}$ $R_L = 16\ \Omega$ , $P_{out} = 220\text{ mW}$ , $20\text{ Hz} \leq F \leq 20\text{ kHz}$		0.15 0.2		%
PSRR	Power supply rejection ratio ( $A_v = 2$ ) $F = 1\text{ kHz}$ , $V_{ripple} = 200\text{ mVpp}$ , input grounded, $C_b = 1\ \mu\text{F}$	50	56		dB
SNR	Signal-to-Noise Ratio (Weighted A, $A_v = 2$ ) ( $R_L = 32\ \Omega$ , THD + N < 0.5%, $20\text{ Hz} \leq F \leq 20\text{ kHz}$ )	80	91		dB
$\phi_M$	Phase margin at unity gain $R_L = 16\ \Omega$ , $C_L = 400\text{ pF}$		58		Degrees
GM	Gain margin $R_L = 16\ \Omega$ , $C_L = 400\text{ pF}$		18		dB
GBP	Gain bandwidth product $R_L = 16\ \Omega$		1.1		MHz
SR	Slew rate $R_L = 16\ \Omega$		0.4		V/ $\mu\text{S}$

Note: All electrical values are guaranteed with correlation measurements at 2 V and 5 V.

**Table 7. Electrical characteristics  $V_{CC} = +2\text{ V}$ ,  $GND = 0\text{ V}$ ,  $T_{amb} = 25\text{ °C}$  (unless otherwise specified)**

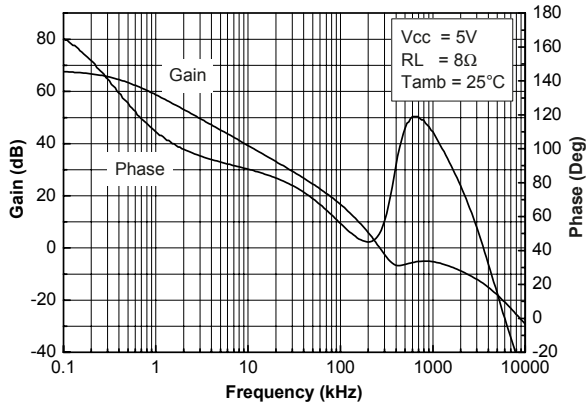
Symbol	Parameter	Min.	Typ.	Max.	Unit
$I_{CC}$	Supply current No input signal, no load		1.7	2.5	mA
$I_{STANDBY}$	Standby current No input signal, $V_{STANDBY} = GND$ for TS421 No input signal, $V_{STANDBY} = V_{CC}$ for TS419		10	1000	nA
$V_{OO}$	Output offset voltage No input signal, $R_L = 16\ \Omega$ or $32\ \Omega$ , $R_{feed} = 20\text{ k}\Omega$		5	25	mV
$P_O$	Output power THD+N = 0.1% Max, $F = 1\text{ kHz}$ , $R_L = 32\ \Omega$		20		mW
	Output power THD+N = 1% Max, $F = 1\text{ kHz}$ , $R_L = 32\ \Omega$	19	23		
	Output power THD+N = 10% Max, $F = 1\text{ kHz}$ , $R_L = 32\ \Omega$		30		
	Output power THD+N = 0.1% Max, $F = 1\text{ kHz}$ , $R_L = 16\ \Omega$		26		
	Output power THD+N = 1% Max, $F = 1\text{ kHz}$ , $R_L = 16\ \Omega$	24	30		
	Output power THD+N = 10% Max, $F = 1\text{ kHz}$ , $R_L = 16\ \Omega$		40		
THD + N	Total harmonic distortion + noise ( $A_v = 2$ ) $R_L = 32\ \Omega$ , $P_{out} = 150\text{ mW}$ , $20\text{ Hz} \leq F \leq 20\text{ kHz}$ $R_L = 16\ \Omega$ , $P_{out} = 220\text{ mW}$ , $20\text{ Hz} \leq F \leq 20\text{ kHz}$		0.1 0.15		%
PSRR	Power supply rejection ratio ( $A_v = 2$ ) <sup>(1)</sup> $F = 1\text{ kHz}$ , $V_{ripple} = 200\text{ mVpp}$ , input grounded, $C_b = 1\ \mu\text{F}$	49	54		dB
SNR	Signal-to-Noise Ratio (Weighted A, $A_v = 2$ ) <sup>(1)</sup> ( $R_L = 32\ \Omega$ , THD + N < 0.5%, $20\text{ Hz} \leq F \leq 20\text{ kHz}$ )	80	89		dB
$\phi_M$	Phase margin at unity gain $R_L = 16\ \Omega$ , $C_L = 400\text{ pF}$		58		Degrees
GM	Gain margin $R_L = 16\ \Omega$ , $C_L = 400\text{ pF}$		20		dB
GBP	Gain bandwidth product $R_L = 16\ \Omega$		1.1		MHz
SR	Slew rate $R_L = 16\ \Omega$		0.4		V/ $\mu\text{S}$

1. Guaranteed by design and evaluation.

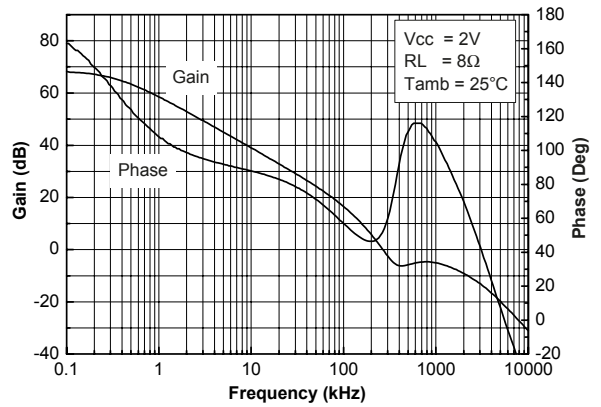


## 4 Electrical characteristics curves

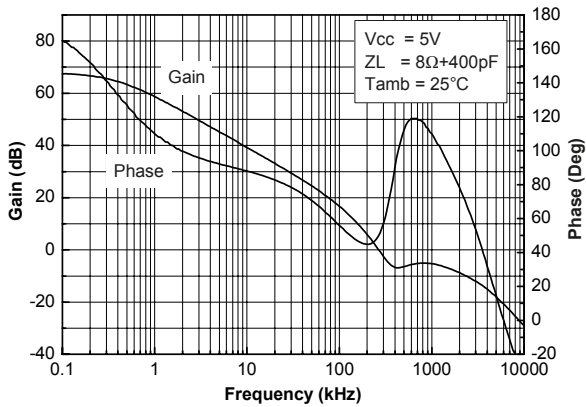
**Figure 2. Open loop gain and phase vs. frequency**



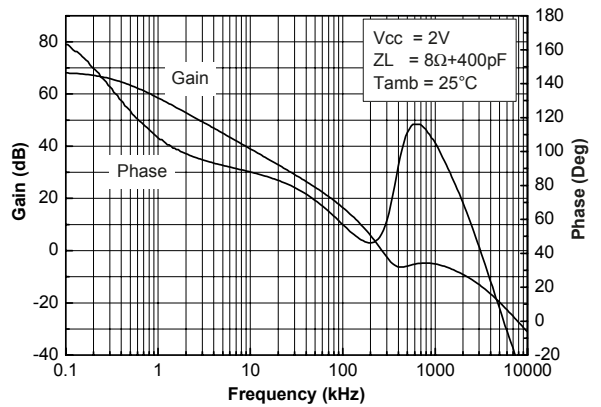
**Figure 3. Open loop gain and phase vs. frequency  
 $V_{CC} = 2V$**



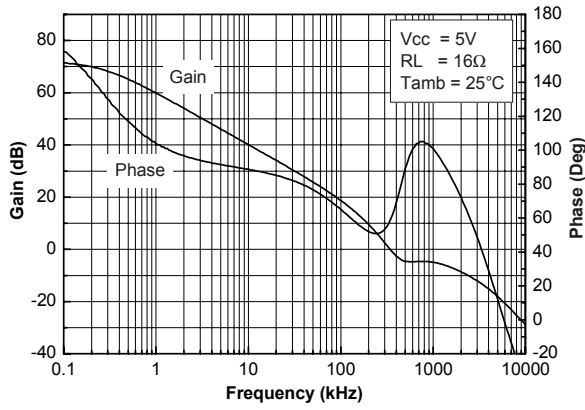
**Figure 4. Open loop gain and phase vs. frequency  
 $V_{CC} = 5V$**



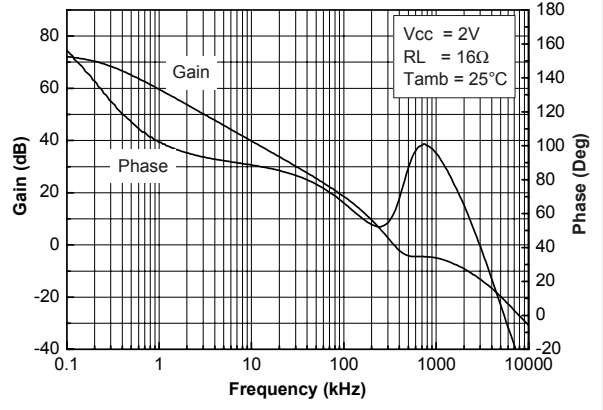
**Figure 5. Open loop gain and phase vs. frequency  
 $Z_L = 8\Omega$**



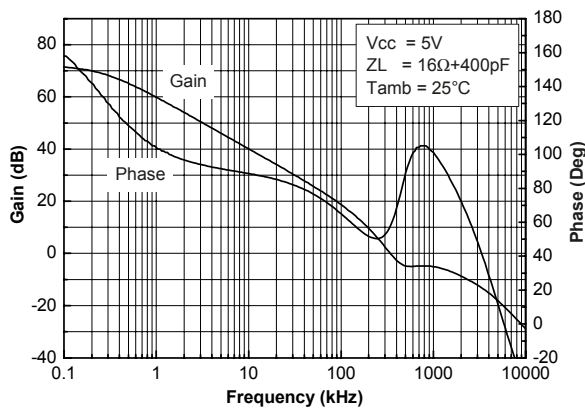
**Figure 6. Open loop gain and phase vs. frequency**  
RL = 16 Ω



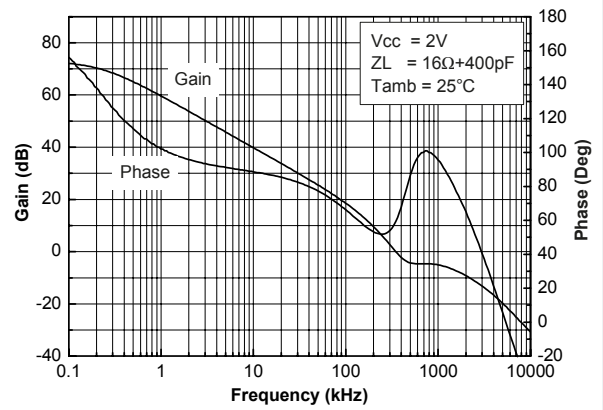
**Figure 7. Open loop gain and phase vs. frequency**  
RL = 16 Ω, Vcc = 2 V



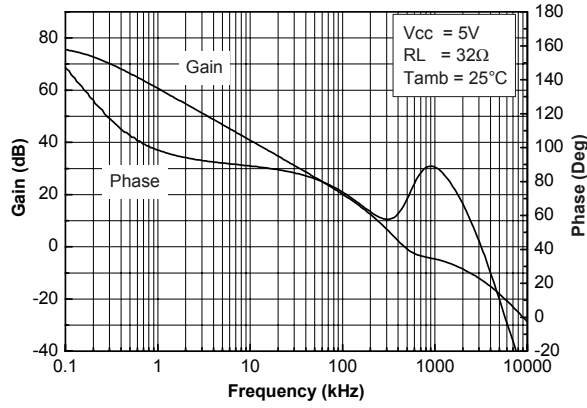
**Figure 8. Open loop gain and phase vs. frequency**  
ZL = 16 Ω, Vcc = 5 V



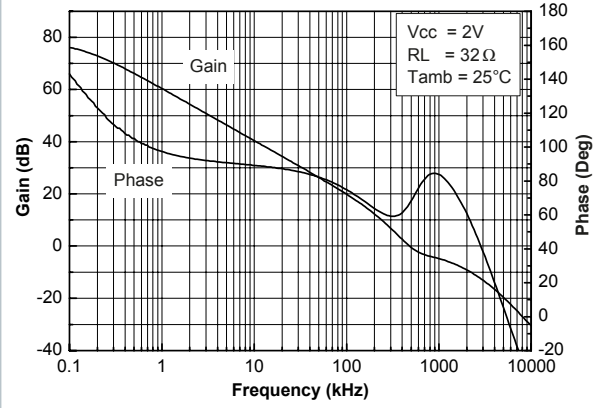
**Figure 9. Open loop gain and phase vs. frequency**  
ZL = 16 Ω, Vcc = 2 V



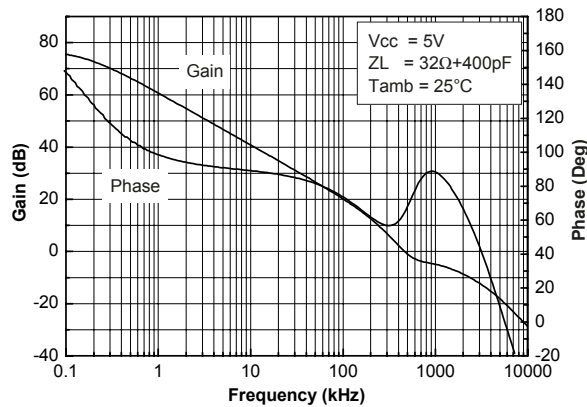
**Figure 10. Open loop gain and phase vs. frequency**  
RL = 32 Ω



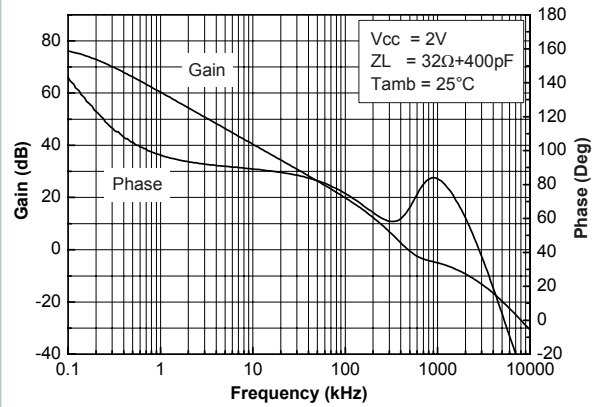
**Figure 11. Open loop gain and phase vs. frequency**  
RL = 32 Ω, Vcc = 2 V



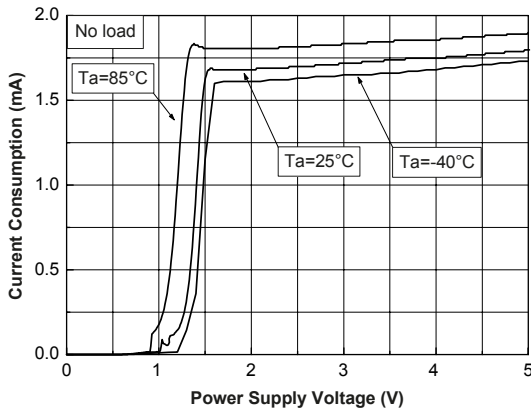
**Figure 12. Open loop gain and phase vs. frequency**  
ZL = 32 Ω



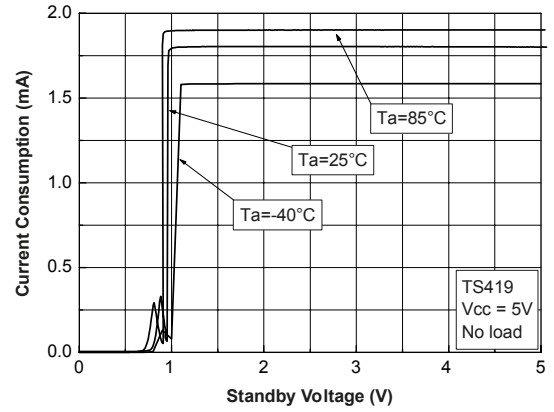
**Figure 13. Open loop gain and phase vs. frequency**  
ZL = 32 Ω, Vcc = 2 V



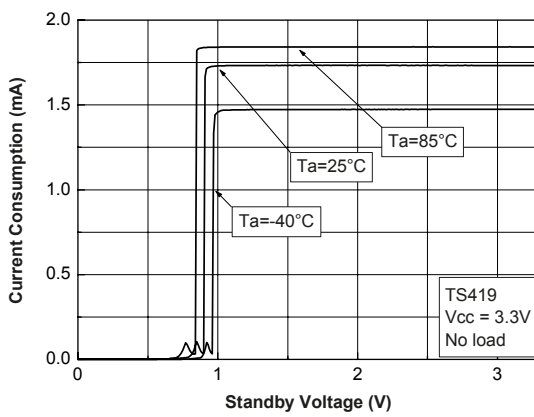
**Figure 14. Current consumption vs. power supply voltage**



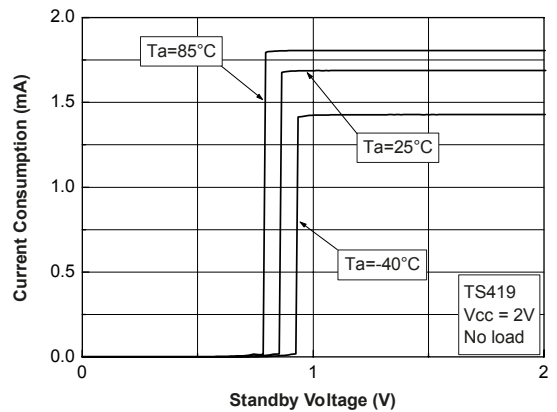
**Figure 15. Current consumption vs. standby voltage Vcc = 5 V**



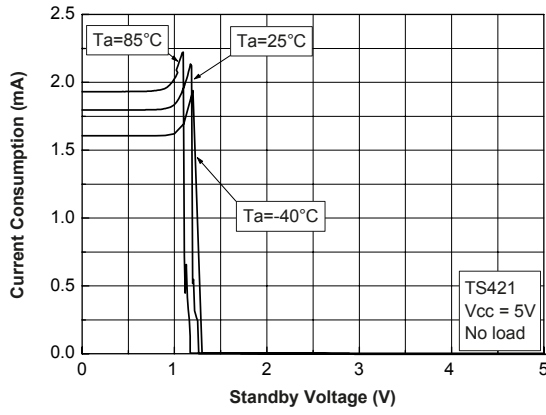
**Figure 16. Current consumption vs. standby voltage Vcc = 3.3 V**



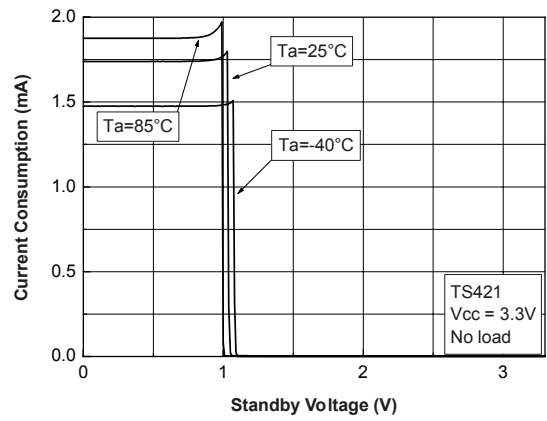
**Figure 17. Current consumption vs. standby voltage Vcc = 2 V**



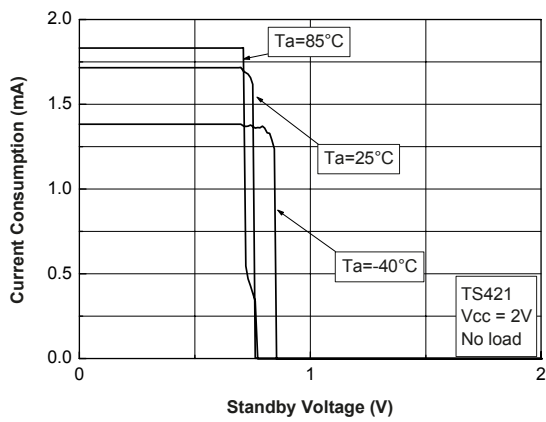
**Figure 18. Current consumption vs. standby voltage  $V_{CC} = 5\text{ V}$  (TS421)**



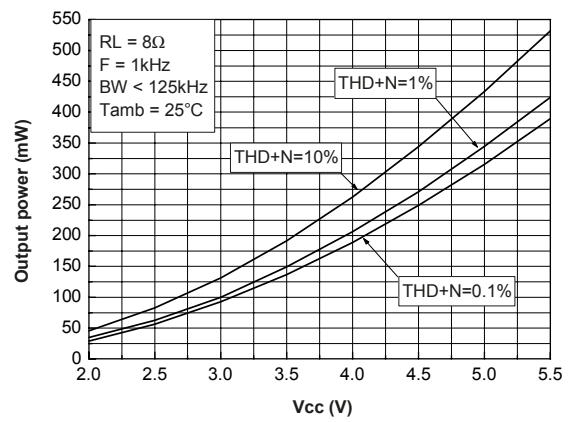
**Figure 19. Current consumption vs. standby voltage  $V_{CC} = 3.3\text{ V}$  (TS421)**



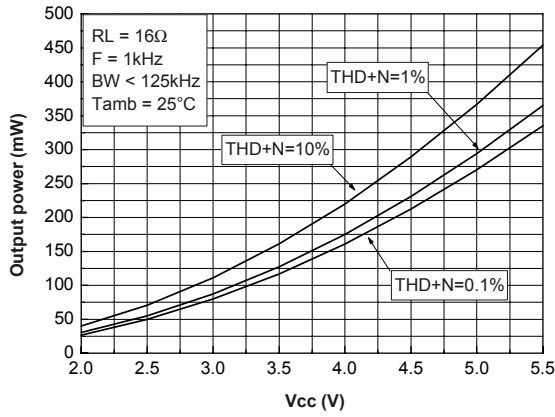
**Figure 20. Current consumption vs. standby voltage  $V_{CC} = 2\text{ V}$  (TS421)**



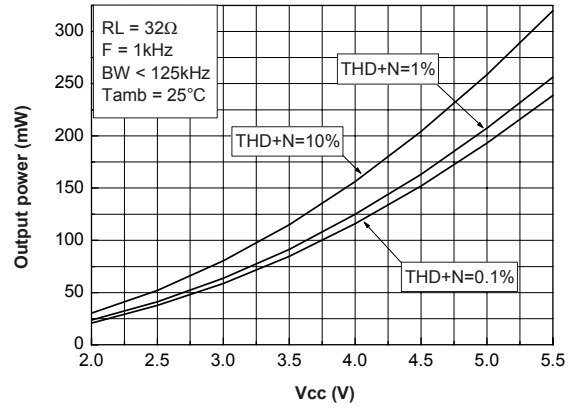
**Figure 21. Output power vs. power supply voltage  $R_L = 8\ \Omega$**



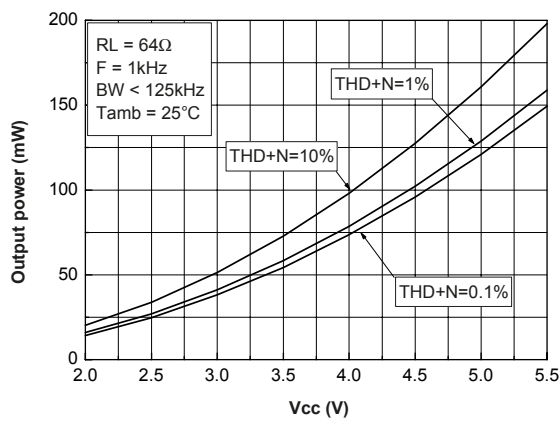
**Figure 22. Output power vs. power supply voltage**  
RL = 16 Ω



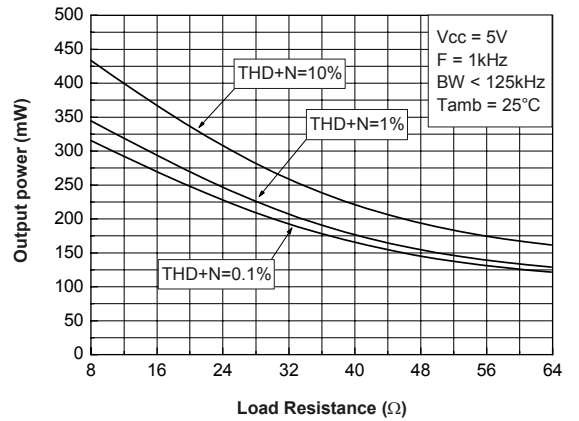
**Figure 23. Output power vs. power supply voltage**  
RL = 32 Ω



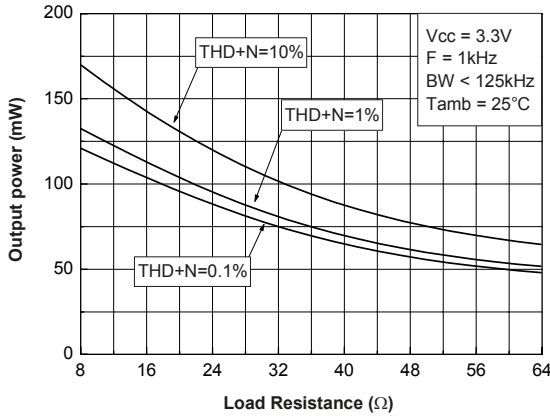
**Figure 24. Output power vs. power supply voltage**  
RL = 64 Ω



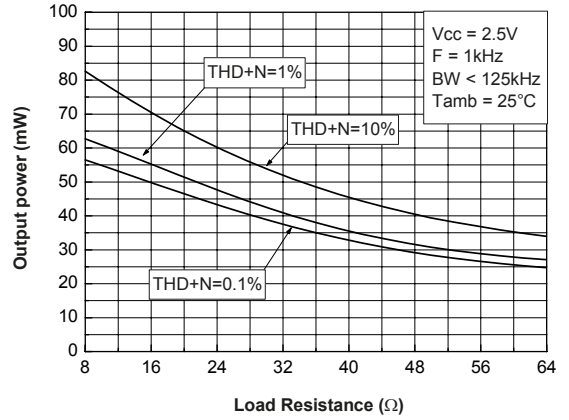
**Figure 25. Output power vs. load resistor Vcc = 5 V**



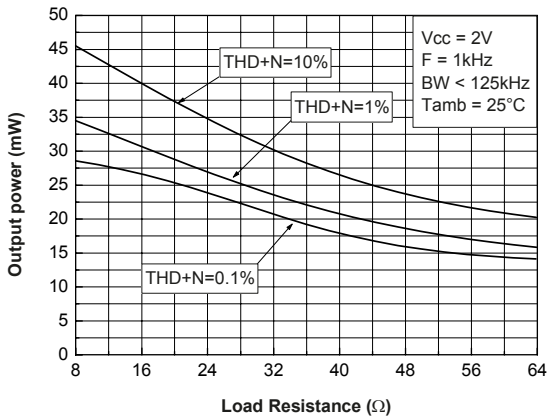
**Figure 26. Output power vs. load resistor**  
**V<sub>CC</sub> = 3.3 V**



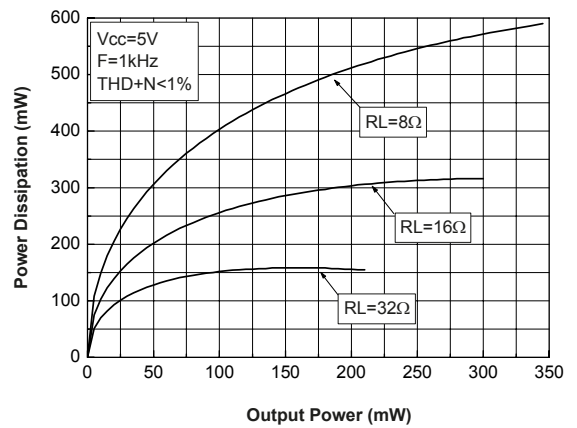
**Figure 27. Output power vs. load resistor**  
**V<sub>CC</sub> = 2.5 V**



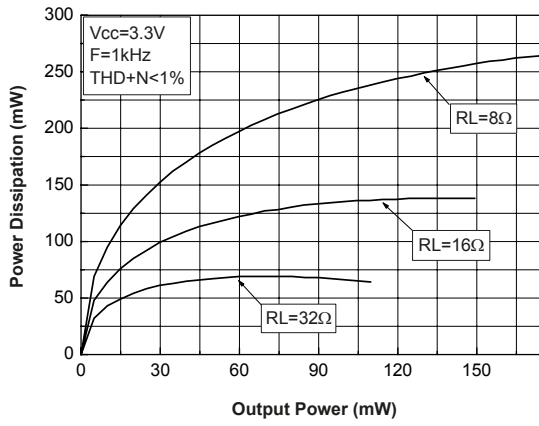
**Figure 28. Output power vs. load resistor** **V<sub>CC</sub> = 2 V**



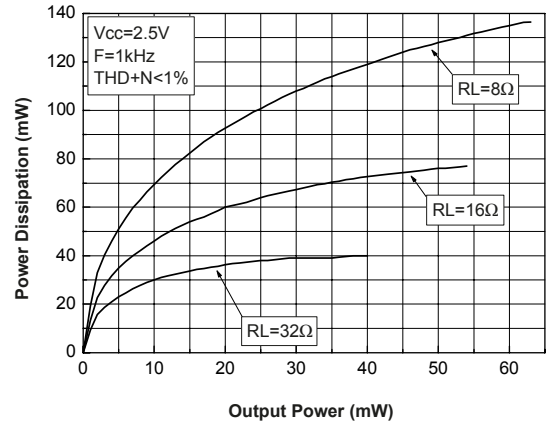
**Figure 29. Power dissipation vs. output power**  
**V<sub>CC</sub> = 5 V**



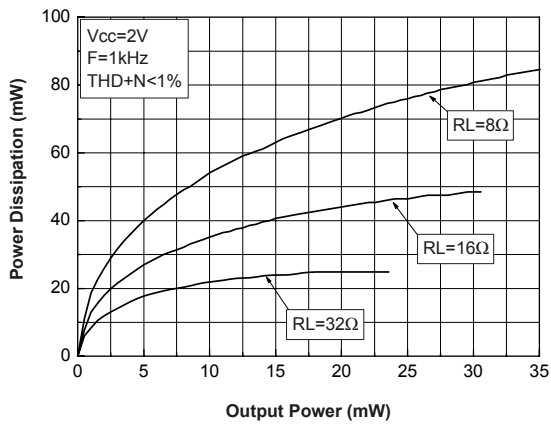
**Figure 30. Power dissipation vs. output power**  
Vcc = 3.3 V



**Figure 31. Power dissipation vs. output power**  
Vcc = 2.5 V



**Figure 32. Power dissipation vs. output power**  
Vcc = 2 V



**Figure 33. Power derating curves**

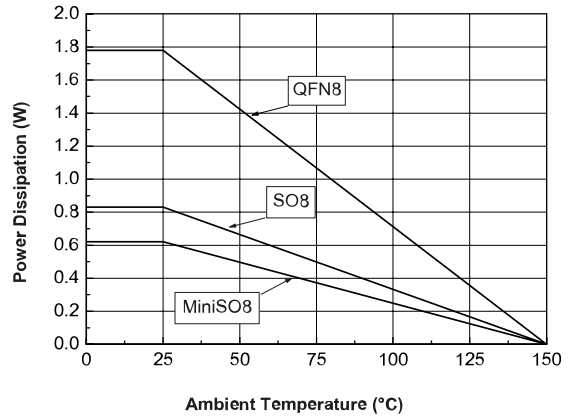




Figure 34. Output voltage swing for one Amp. vs. power supply voltage

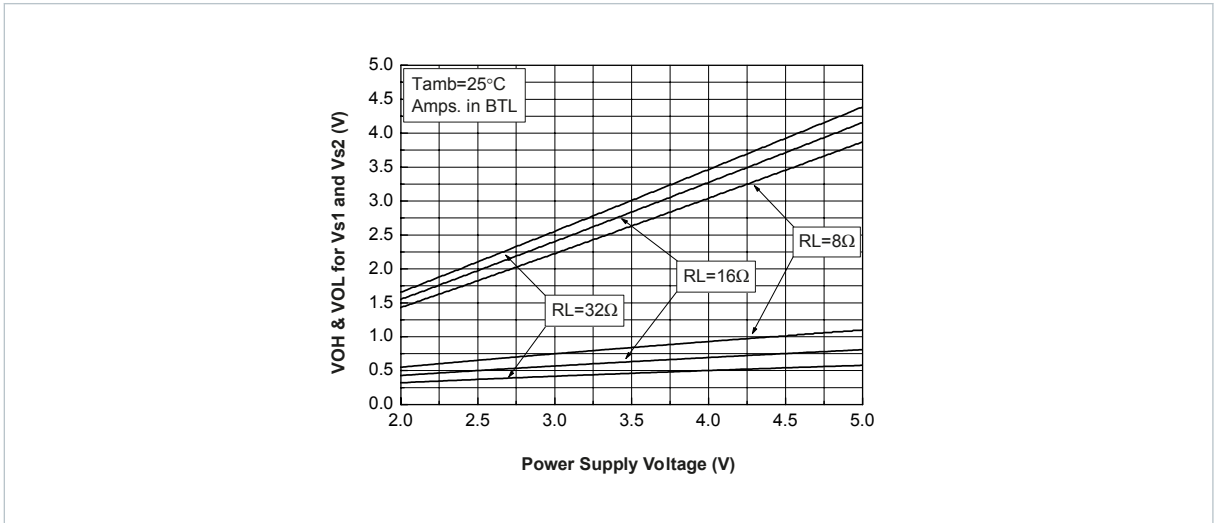


Figure 35. THD + N vs. output power RL = 8 Ω

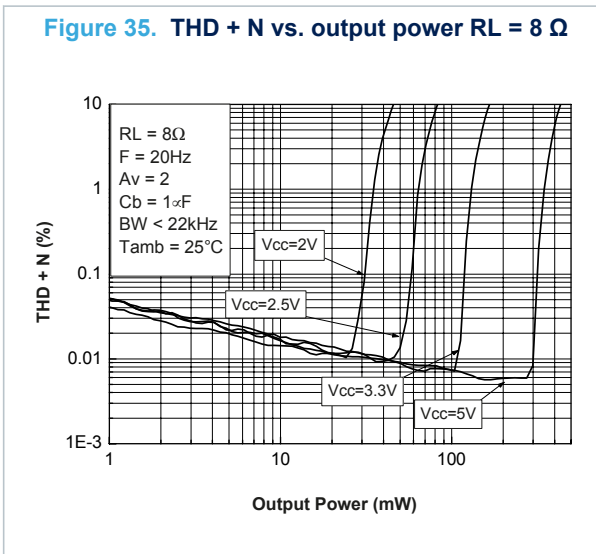


Figure 36. THD + N vs. output power RL = 16 Ω

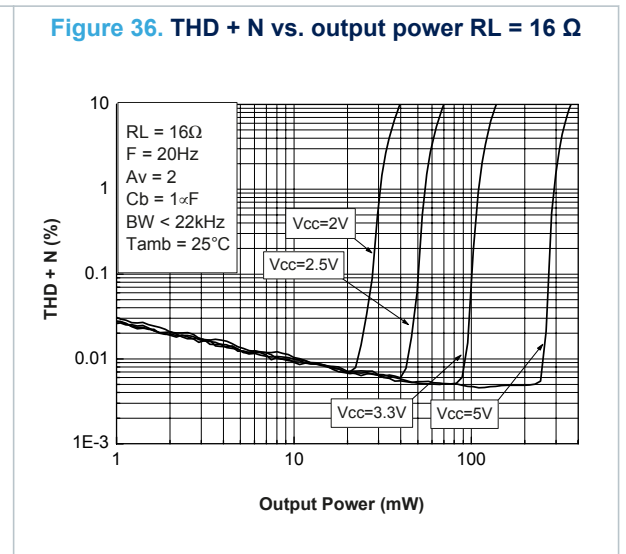


Figure 37. THD + N vs. output power  $R_L = 32 \Omega$

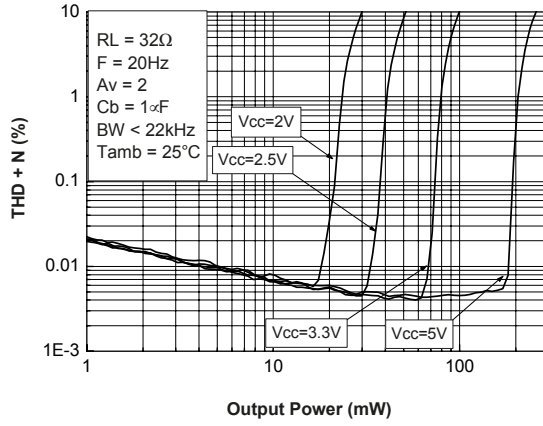


Figure 38. THD + N vs. output power  $R_L = 8 \Omega$ ,  $A_v = 2$

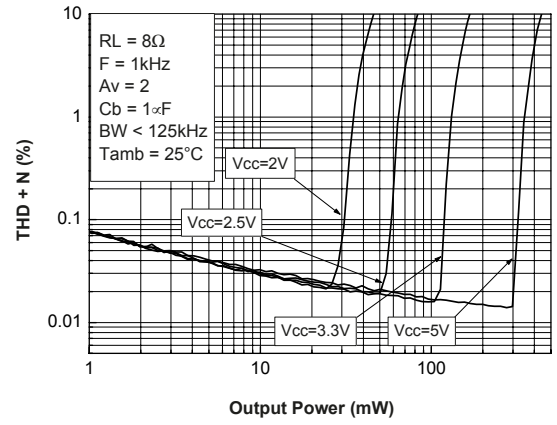


Figure 39. THD + N vs. output power  $R_L = 16 \Omega$ ,  $A_v = 2$

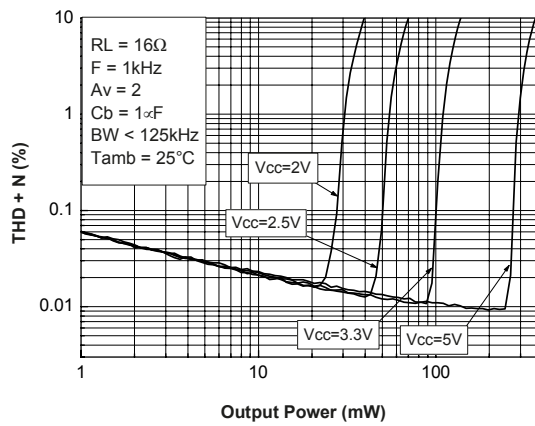
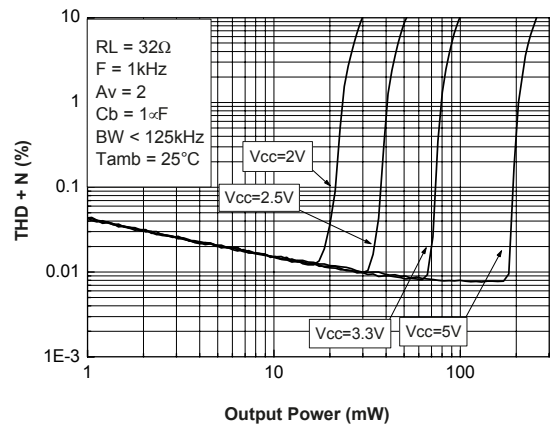
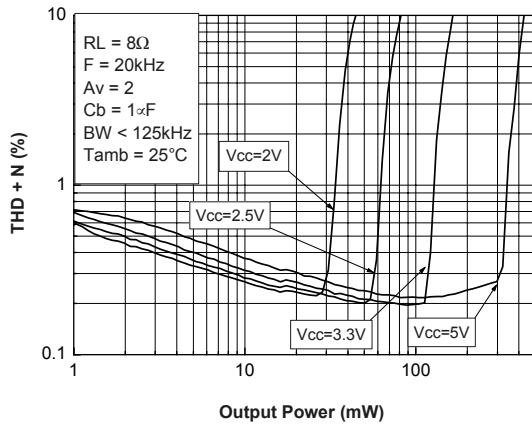


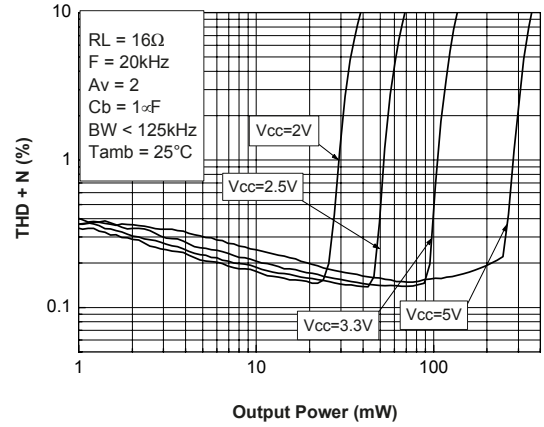
Figure 40. THD + N vs. output power  $R_L = 32 \Omega$ ,  $A_v = 2$



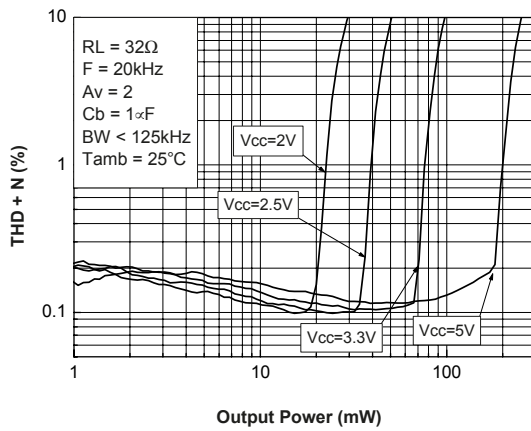
**Figure 41. THD + N vs. output power RL = 8 Ω, Cb = 1 μF**



**Figure 42. THD + N vs. output power RL = 16 Ω, Cb = 1 μF**



**Figure 43. THD + N vs. output power RL = 32 Ω, Cb = 1 μF**



**Figure 44. THD + N vs. frequency RL = 8 Ω**

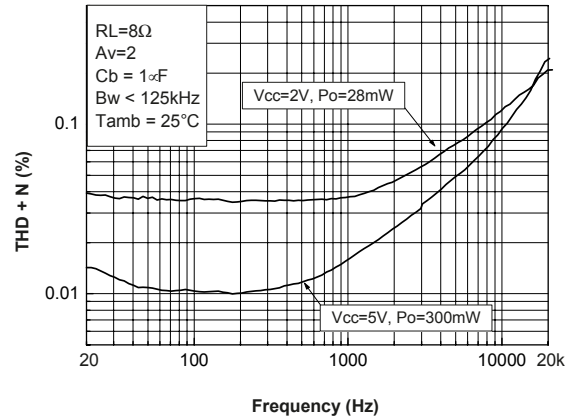


Figure 45. THD + N vs. frequency RL = 16 Ω

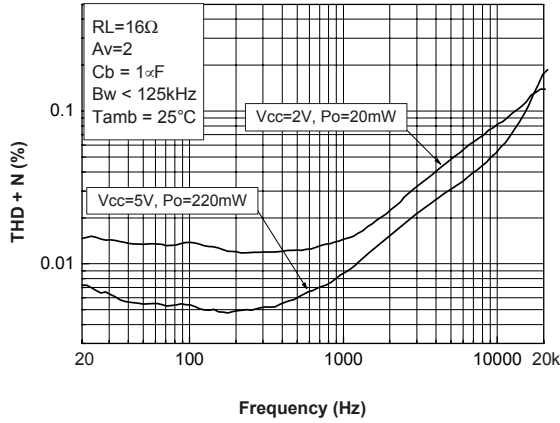


Figure 46. THD + N vs. frequency RL = 32 Ω

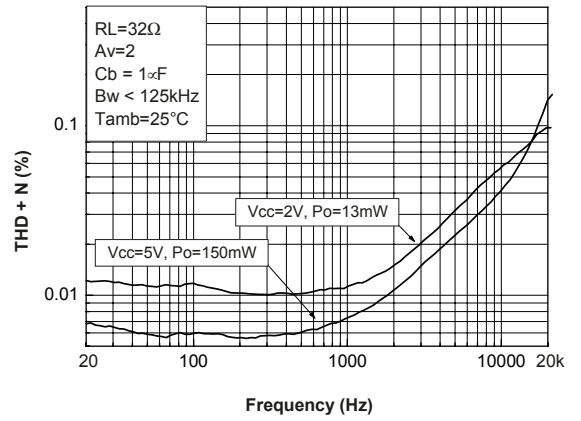


Figure 47. Signal to noise ratio vs. power supply voltage with unweighted filter (20 Hz to 20 kHz)

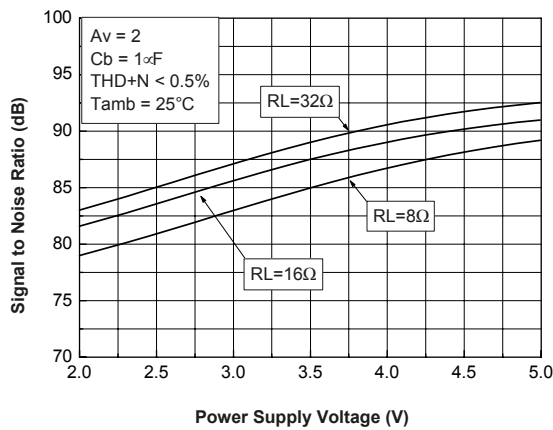


Figure 48. Signal to noise ratio vs. power supply voltage with weighted filter Type A

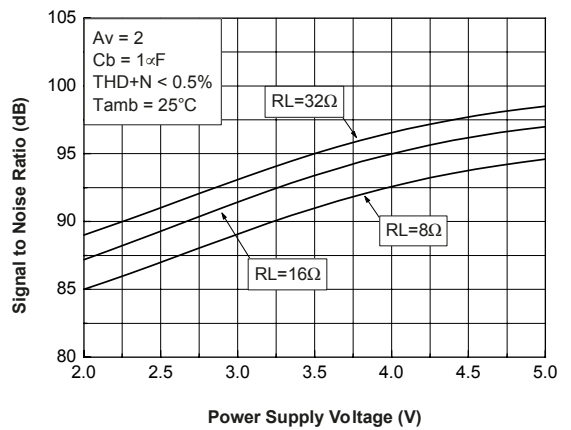


Figure 49. Noise floor Vcc = 5 V

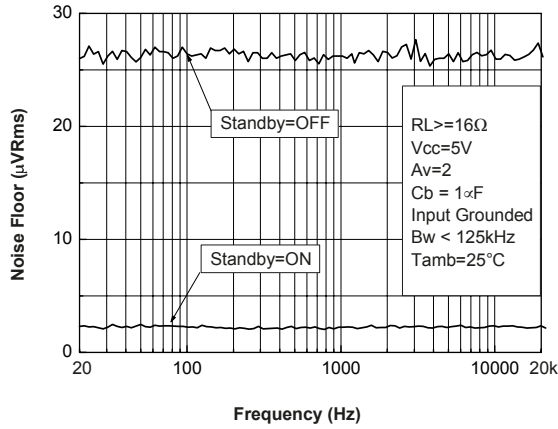


Figure 50. Noise floor Vcc = 2 V

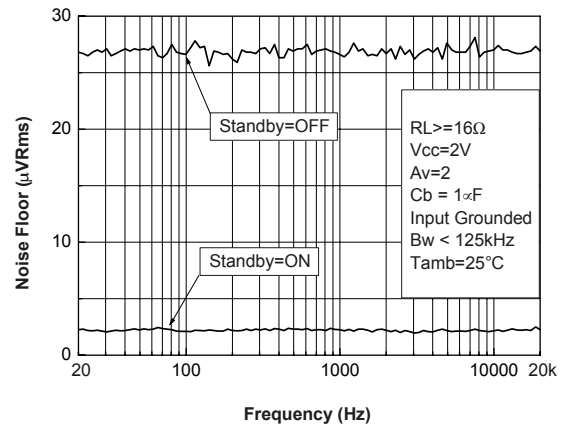


Figure 51. PSRR vs. input capacitor

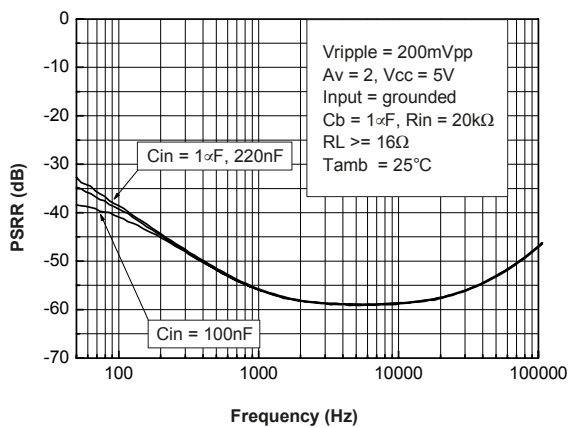
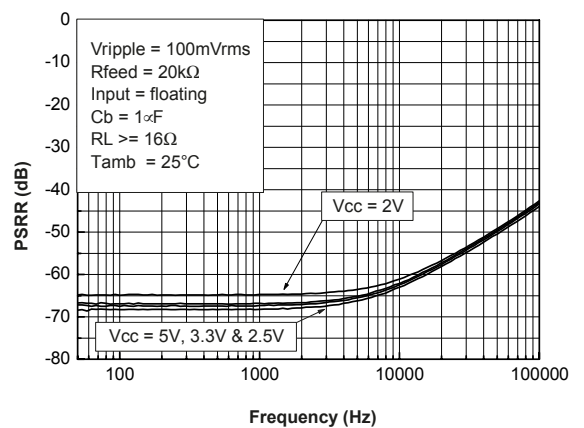
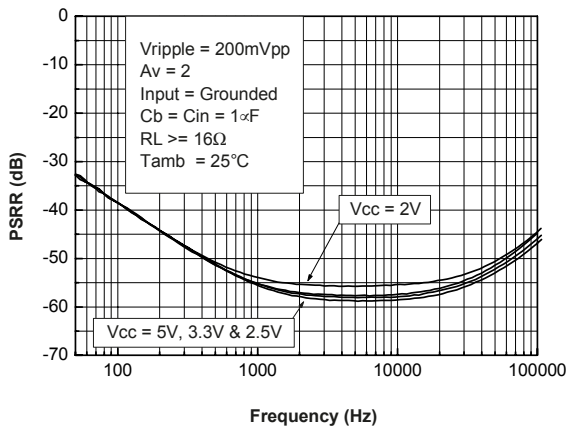


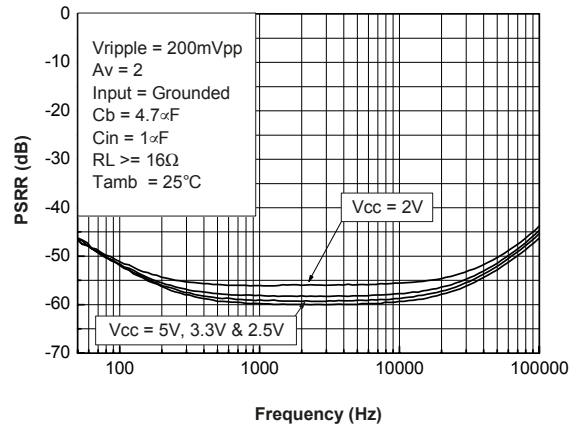
Figure 52. PSRR vs. power supply voltage



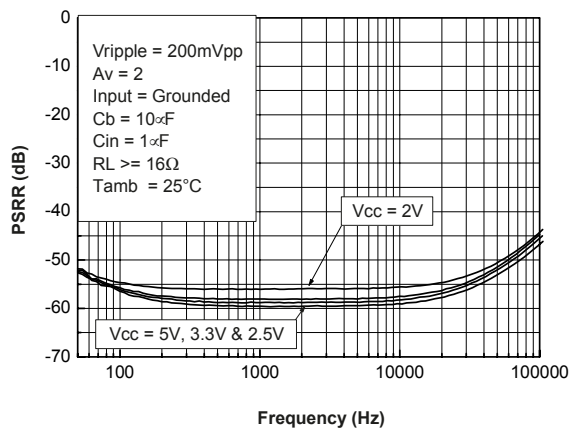
**Figure 53. PSRR vs. bypass capacitor**  
Cb = Cin = 1  $\mu$ F



**Figure 54. PSRR vs. bypass capacitor Cb = 4.7  $\mu$ F**



**Figure 55. PSRR vs. bypass capacitor Cb = 10  $\mu$ F**



**Figure 56. THD + N vs. output power RL = 8  $\Omega$**

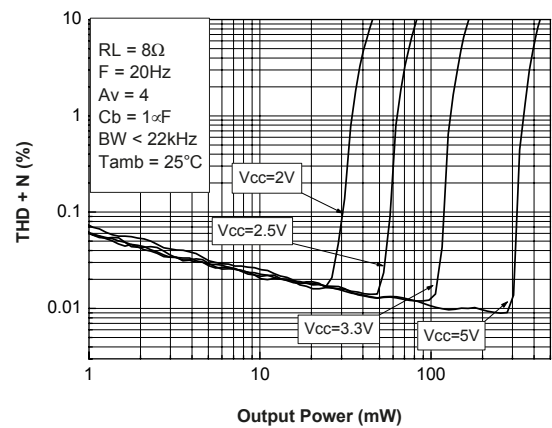


Figure 57. THD + N vs. output power RL = 16 Ω

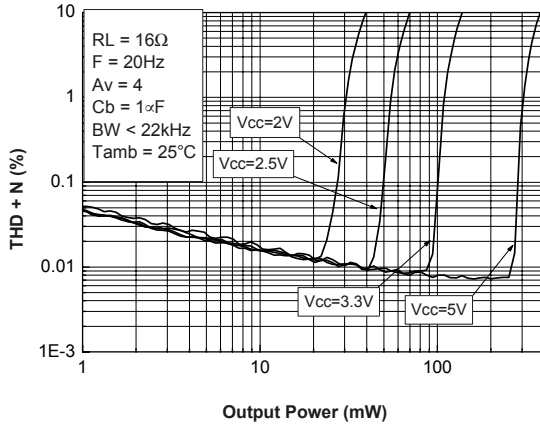


Figure 58. THD + N vs. output power RL = 32 Ω

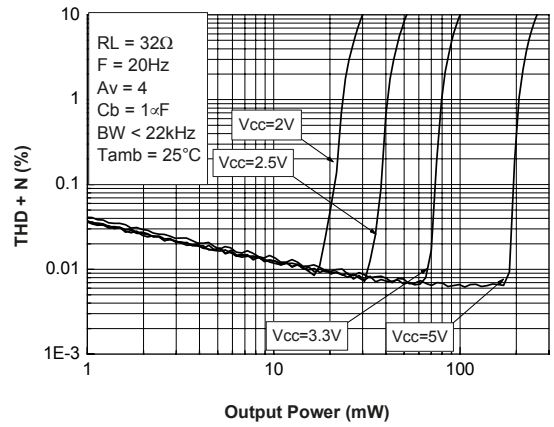


Figure 59. THD + N vs. output power RL = 8 Ω, Av = 4

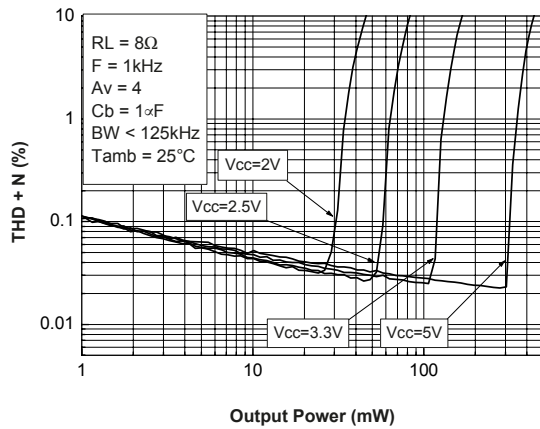


Figure 60. THD + N vs. output power RL = 16 Ω, Av = 4

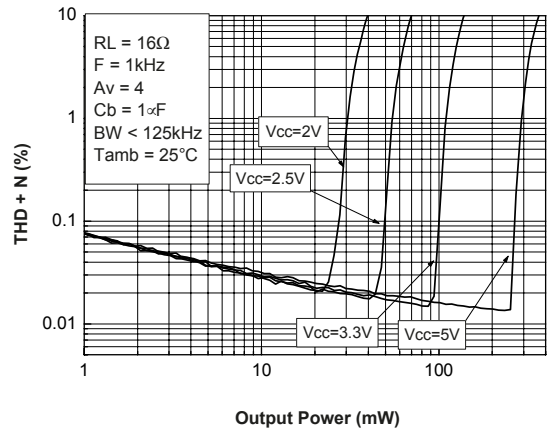


Figure 61. THD + N vs. output power  $R_L = 32 \Omega$ ,  $A_v = 4$

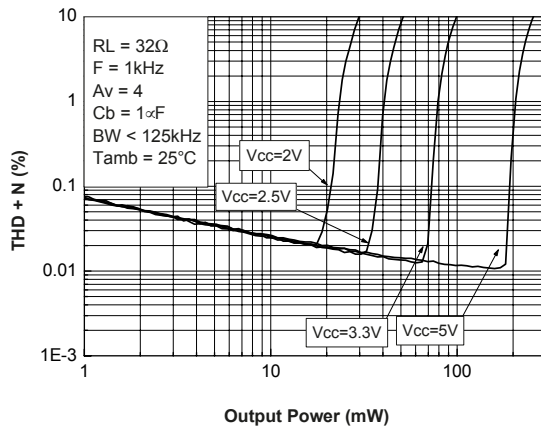


Figure 62. THD + N vs. output power  $R_L = 8 \Omega$

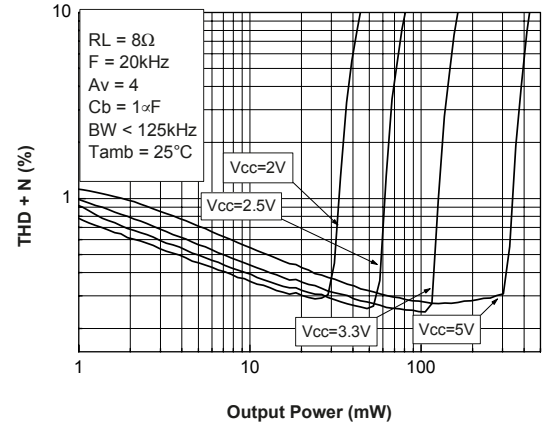


Figure 63. THD + N vs. output power  $R_L = 16 \Omega$

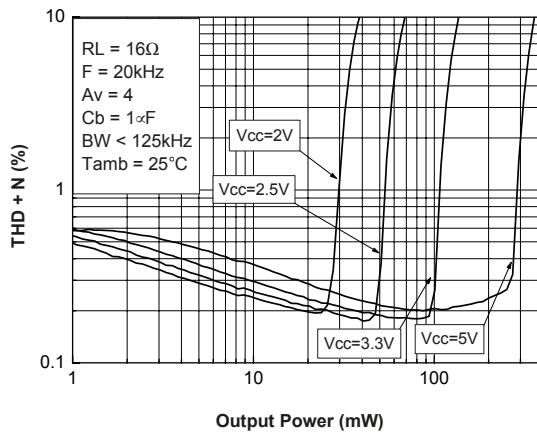


Figure 64. THD + N vs. output power  $R_L = 32 \Omega$

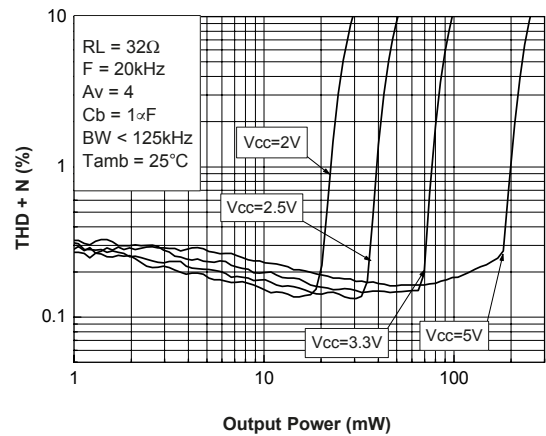




Figure 65. THD + N vs. frequency RL = 8 Ω

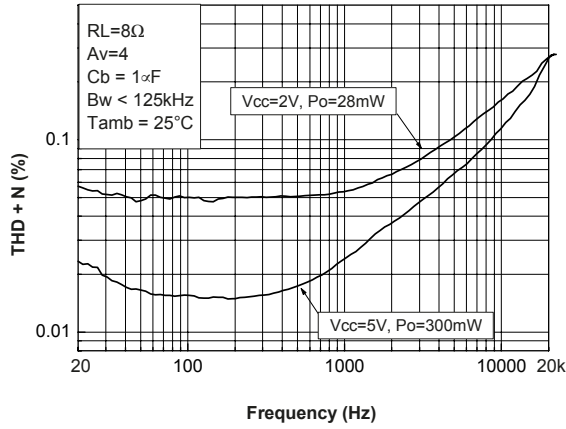


Figure 66. THD + N vs. frequency RL = 16 Ω

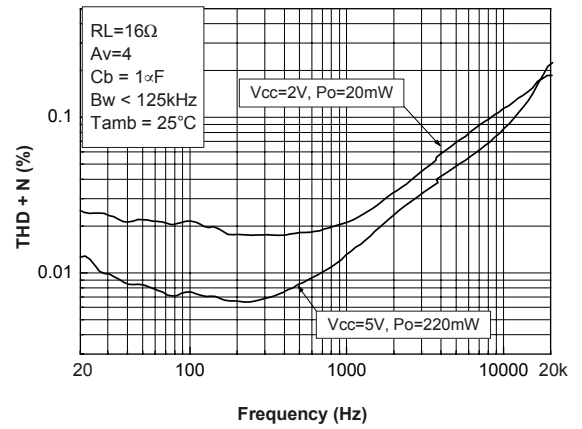


Figure 67. THD + N vs. frequency RL = 32 Ω

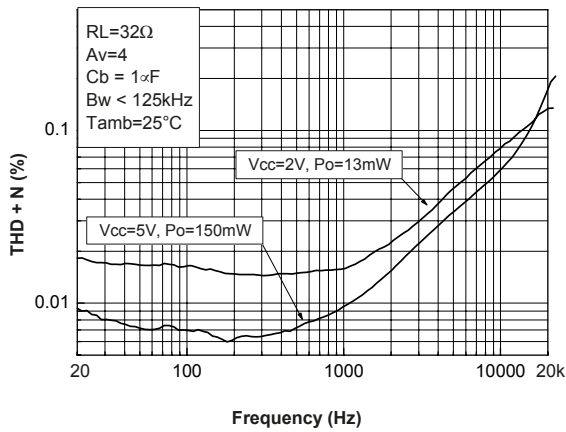
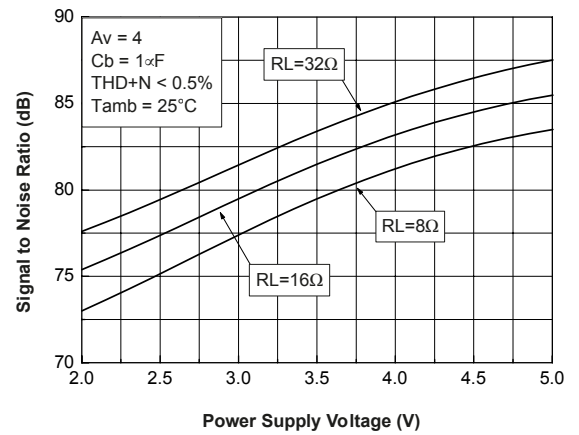
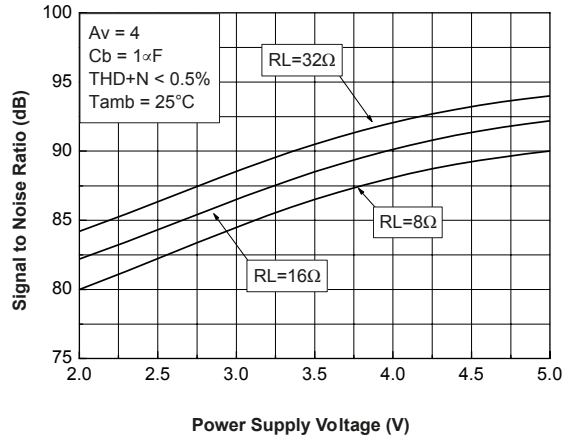


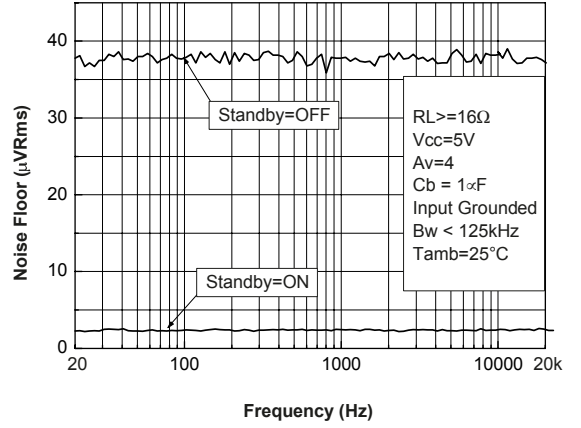
Figure 68. Signal-to-noise ratio vs. power supply voltage with unweighted filter (20 Hz to 20 kHz)



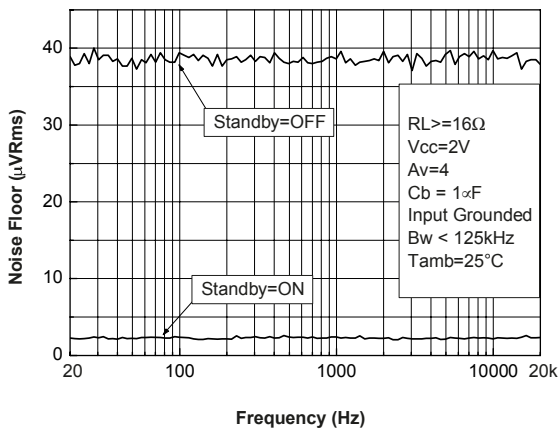
**Figure 69. Signal-to-noise ratio vs power supply voltage with weighted filter Type A**



**Figure 70. Noise floor  $V_{cc} = 5 V$**



**Figure 71. Noise floor  $V_{cc} = 2 V$**



**Figure 72. PSRR vs. power supply voltage**

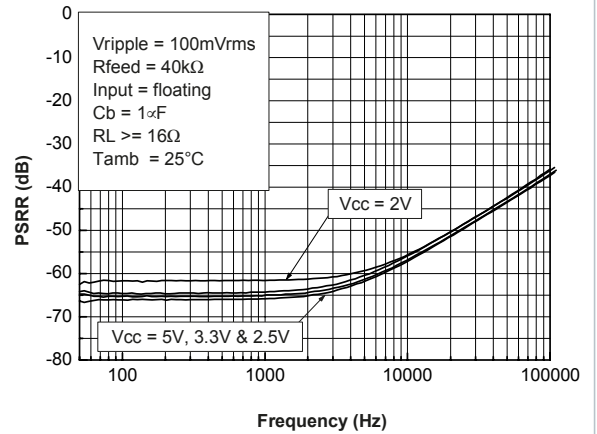


Figure 73. PSRR vs. input capacitor

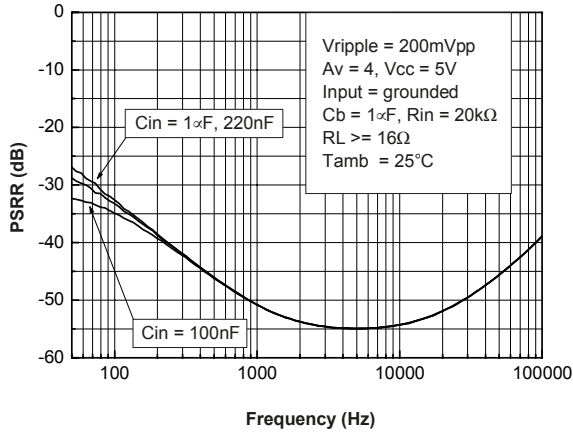


Figure 74. PSRR vs. bypass capacitor  
Cb = Cin = 1 µF

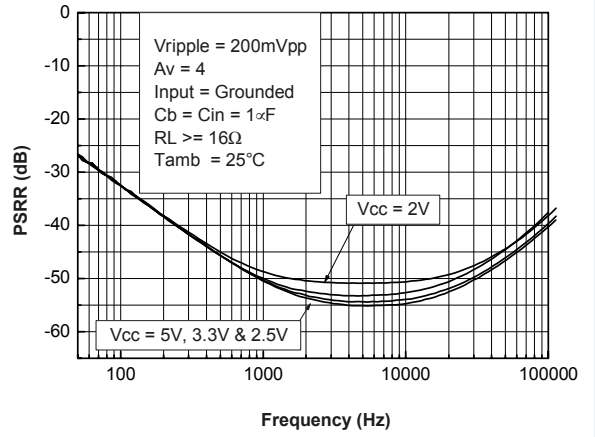


Figure 75. PSRR vs. bypass capacitor  
Cb = Cin = 4.7 µF

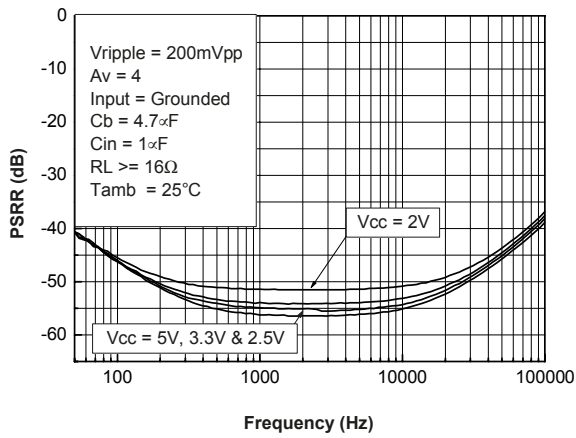


Figure 76. PSRR vs. bypass capacitor  
Cb = Cin = 10 µF

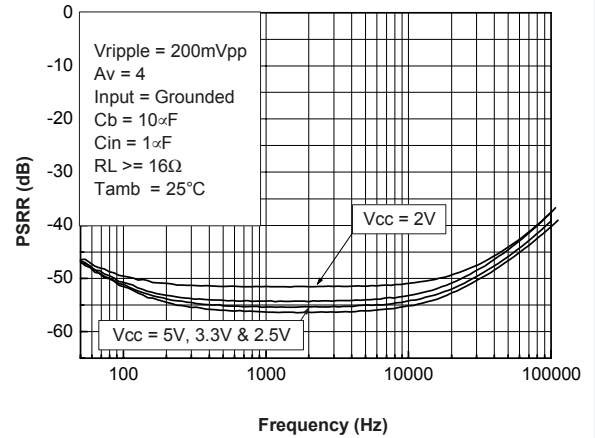


Figure 77. THD + N vs. output power RL = 8 Ω

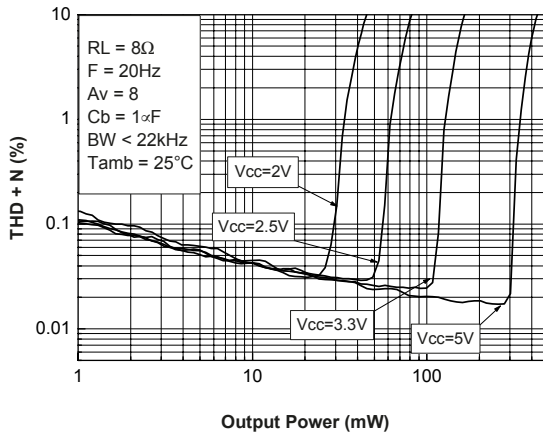


Figure 78. THD + N vs. output power RL = 16 Ω

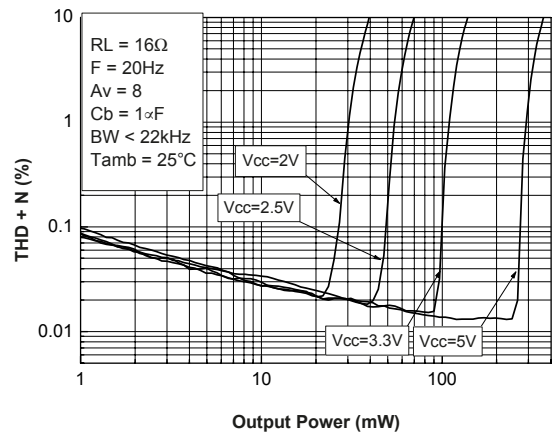


Figure 79. THD + N vs. output power RL = 32 Ω

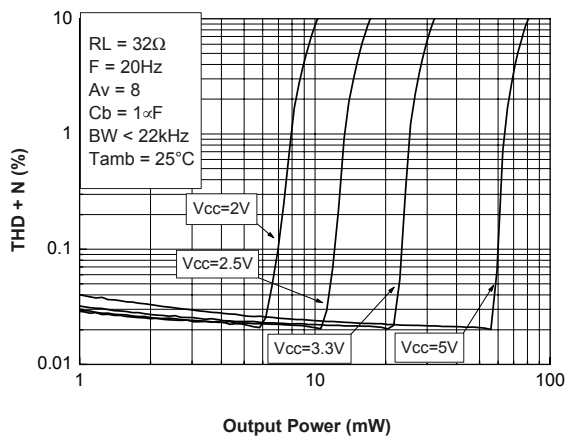
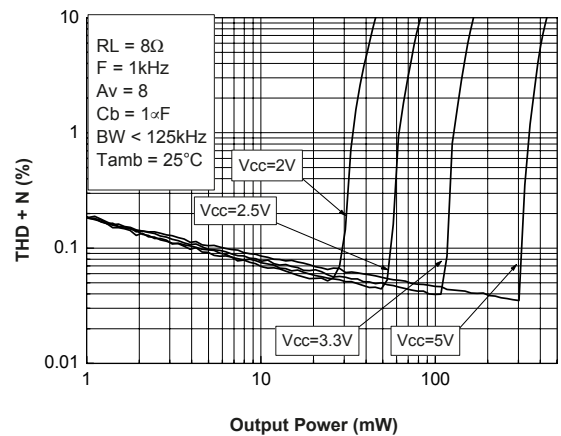
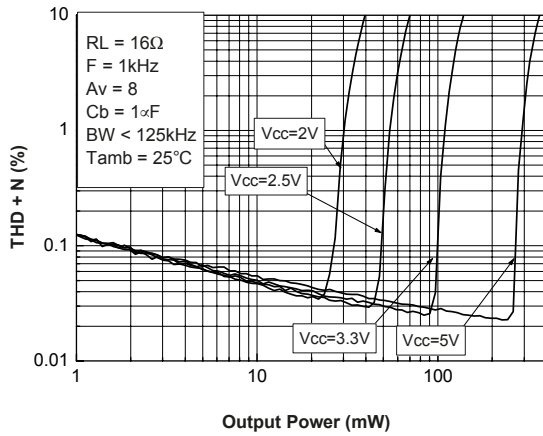


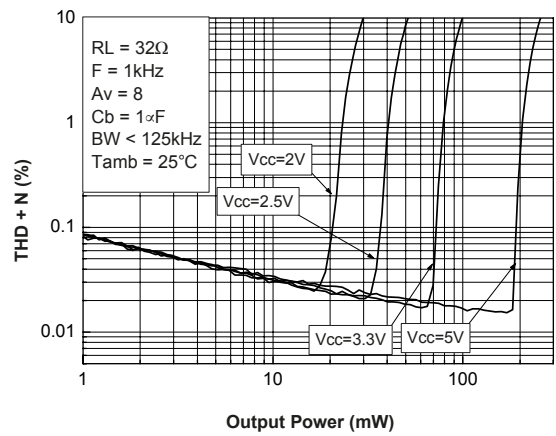
Figure 80. THD + N vs. output power RL = 8 Ω, Av = 8



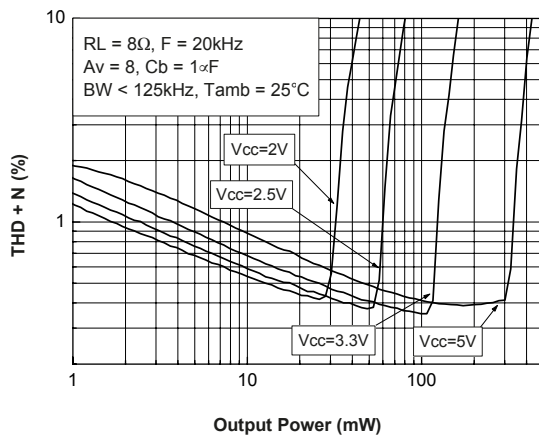
**Figure 81. THD + N vs. output power RL = 16 Ω, Av = 8**



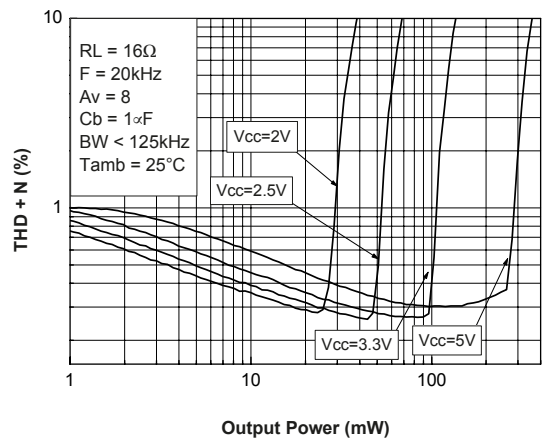
**Figure 82. THD + N vs. output power RL = 32 Ω, Av = 8**



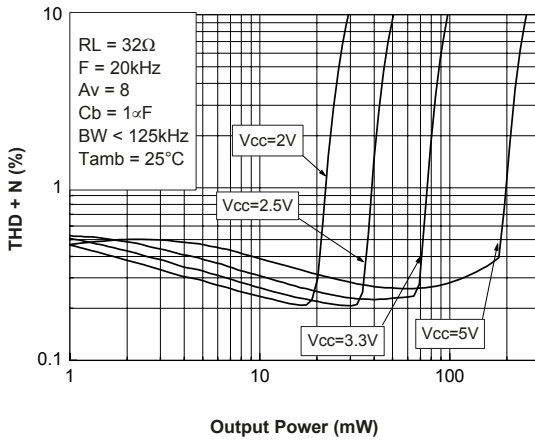
**Figure 83. THD + N vs. output power RL = 8 Ω, Cb = 1 μF**



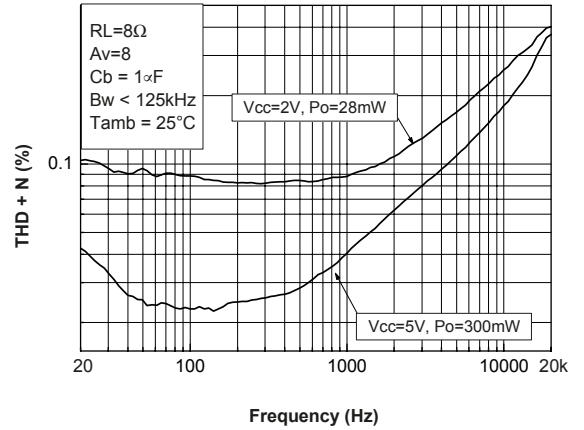
**Figure 84. THD + N vs. output power RL = 16 Ω, Cb = 1 μF**



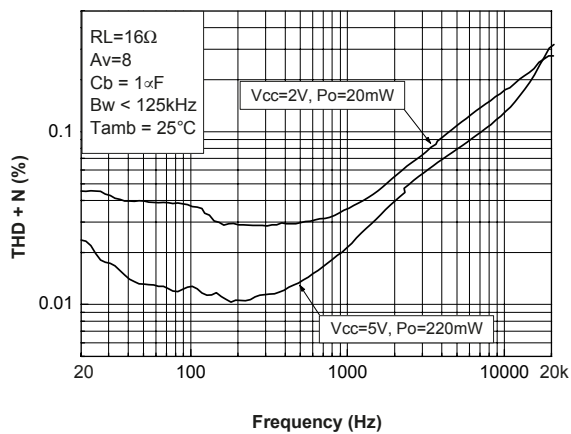
**Figure 85. THD + N vs. output power RL = 32  $\Omega$ , Cb = 1  $\mu$ F**



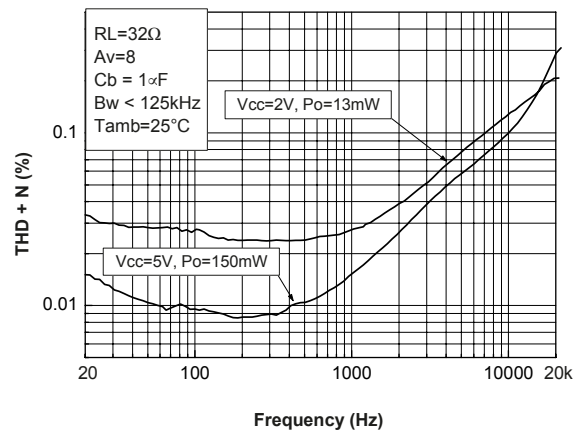
**Figure 86. THD + N vs. frequency RL = 8  $\Omega$**



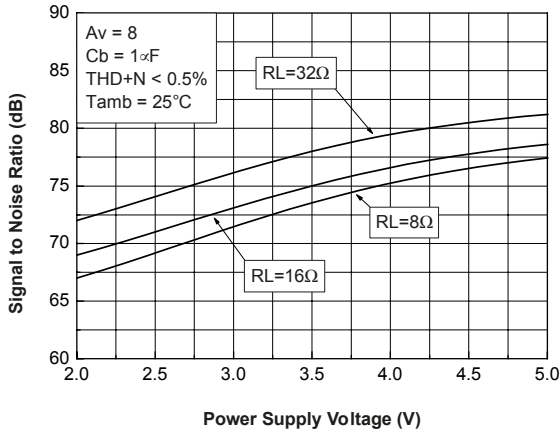
**Figure 87. THD + N vs. frequency RL = 16  $\Omega$**



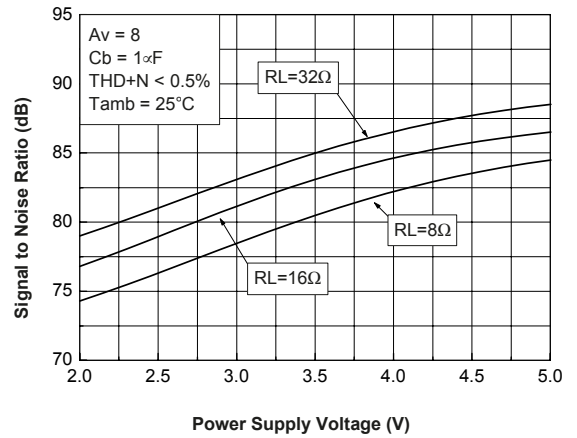
**Figure 88. THD + N vs. frequency RL = 32  $\Omega$**



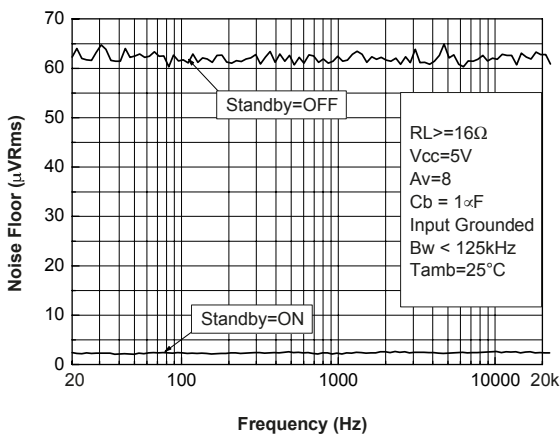
**Figure 89. Signal to noise ratio vs. power supply voltage with unweighted filter (20 Hz to 20 kHz)**



**Figure 90. Signal to noise ratio vs. power supply voltage with weighted filter Type A**



**Figure 91. Noise floor Vcc = 5 V**



**Figure 92. Noise floor Vcc = 2 V**

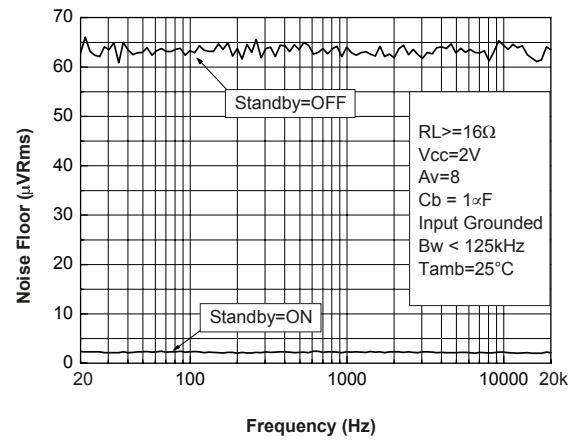


Figure 93. PSRR vs. power supply voltage

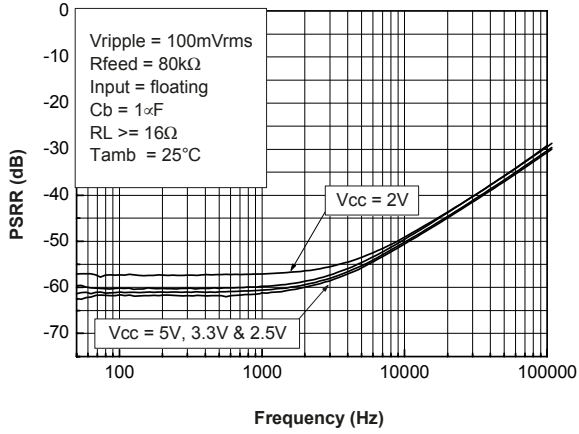


Figure 94. PSRR vs. input capacitor

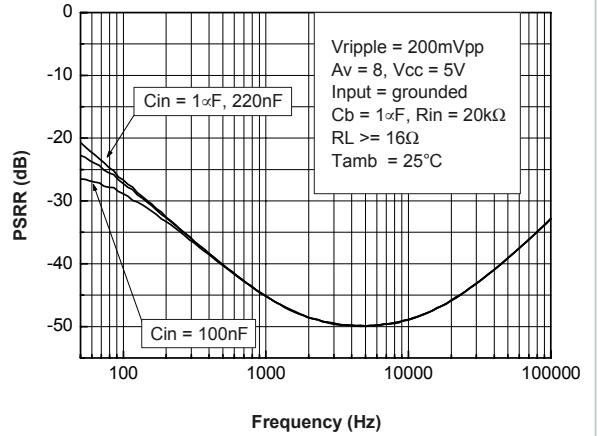


Figure 95. PSRR vs. bypass capacitor  
Cb = Cin = 1  $\mu$ F

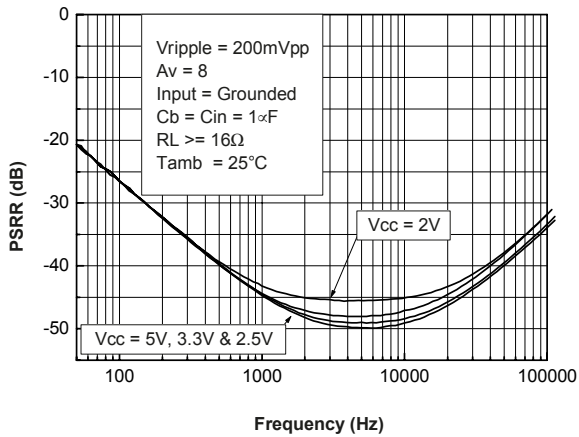


Figure 96. PSRR vs. bypass capacitor Cb = 4.7  $\mu$ F

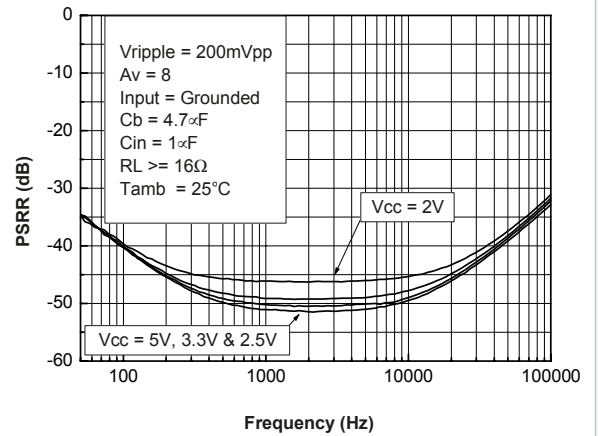
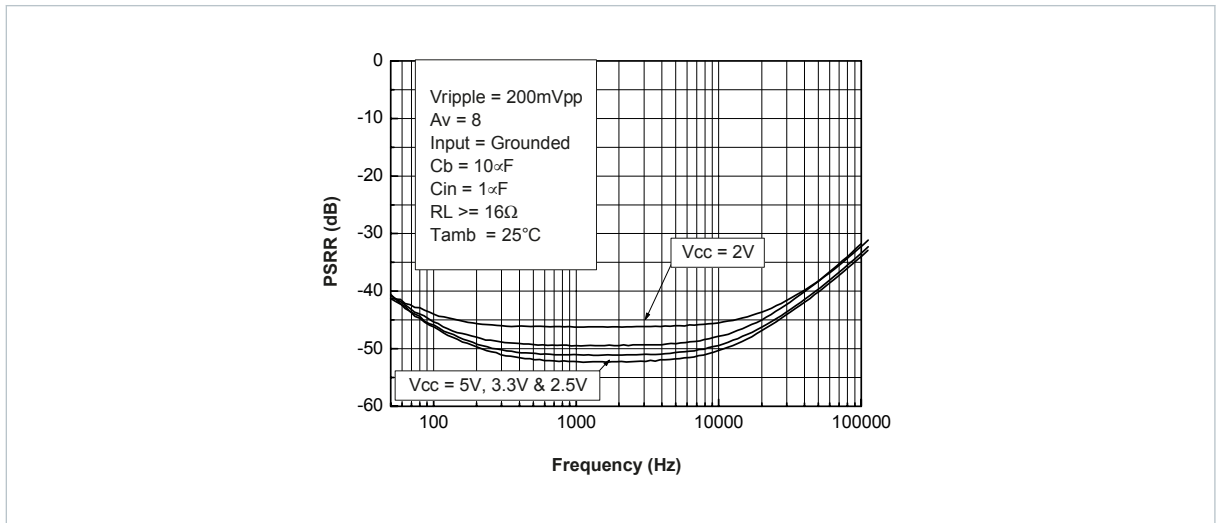




Figure 97. PSRR vs. bypass capacitor  $C_b = 1 \mu\text{F}$



## 5 Application information

### 5.1 BTL configuration principle

The TS419 and TS421 are monolithic power amplifiers with a BTL output type. BTL (Bridge Tied Load) means that each end of the load is connected to two single-ended output amplifiers. Thus, we have:

Single ended output 1 =  $V_{out1} = V_{out}$  (V)

Single ended output 2 =  $V_{out2} = -V_{out}$  (V)

And  $V_{out1} - V_{out2} = 2V_{out}$  (V)

The output power is:

$P_{out} = (2V_{out_{RMS}})^2 / R_L$  (W)

For the same power supply voltage, the output power in BTL configuration is four times higher than the output power in single ended configuration.

### 5.2 Gain in typical application schematic

In flat region (no effect of  $C_{in}$ ), the output voltage of the first stage is:

$$V_{out} = -V_{in} \frac{R_{feed}}{R_{in}} \quad (V) \quad (1)$$

For the second stage :  $V_{out2} = -V_{out1}$  (V)

The differential output voltage is:

$$V_{out2} - V_{out1} = 2V_{in} \frac{R_{feed}}{R_{in}} \quad (V) \quad (2)$$

The differential gain named gain ( $G_v$ ) for more convenient usage is:

$$G_v = \frac{V_{out2} - V_{out1}}{V_{in}} = 2 \frac{R_{feed}}{R_{in}} \quad (3)$$

Remark :  $V_{out2}$  is in phase with  $V_{in}$  and  $V_{out1}$  is 180° phased with  $V_{in}$ . It means that the positive terminal of the loud speaker should be connected to  $V_{out2}$  and the negative to  $V_{out1}$ .

### 5.3 Low and high frequency response

In low frequency region, the effect of  $C_{in}$  starts.  $C_{in}$  with  $R_{in}$  forms a high pass filter with a -3 dB cut-off frequency

$$F_{CL} = \frac{1}{2\pi R_{in} C_{in}} \quad (Hz)$$

In high frequency region, you can limit the bandwidth by adding a capacitor ( $C_{feed}$ ) in parallel on  $R_{feed}$ . Its form a low pass filter with a -3 dB cut-off frequency.

$$F_{CH} = \frac{1}{2\pi R_{feed} C_{feed}} \quad (Hz)$$

### 5.4 Power dissipation and efficiency

Hypothesis:

- Voltage and current in the load are sinusoidal ( $V_{out}$  and  $I_{out}$ )
- Supply voltage is a pure DC source ( $V_{cc}$ )

Regarding the load we have:

$$V_{OUT} = V_{PEAK} \sin \omega t(t) \quad (4)$$

and

$$I_{OUT} = \frac{V_{OUT}}{R_L} \quad (A) \quad (5)$$

$$P_{OUT} = \frac{V_{PEAK}^2}{2R_L} (W) \quad (6)$$

Then, the average current delivered by the supply voltage is:

$$I_{CC_{AVG}} = 2 \frac{V_{PEAK}}{\pi R_L} (A) \quad (7)$$

The power delivered by the supply voltage is  $P_{supply} = V_{CC} I_{CC_{AVG}}$  (W)

Then, the power dissipated by the amplifier is  $P_{diss} = P_{supply} - P_{out}$  (W)

$$P_{diss} = \frac{2\sqrt{2}V_{CC}}{\pi R_L} \sqrt{P_{OUT}} - P_{OUT} (W) \quad (8)$$

and the maximum value is obtained when:

$$\frac{\partial P_{diss}}{\partial P_{OUT}} = 0 \quad (9)$$

and its value is:

$$P_{dissmax} = \frac{2V_{CC}^2}{\pi^2 R_L} (W) \quad (10)$$

Remark : This maximum value is only depending on power supply voltage and load values.

The efficiency is the ratio between the output power and the power supply

$$\eta = \frac{P_{OUT}}{P_{supply}} = \frac{\pi V_{PEAK}}{4V_{CC}} \quad (11)$$

The maximum theoretical value is reached when

$V_{peak} = V_{CC}$ , so

$$\frac{\pi}{4} = 78.5\% \quad (12)$$

## 5.5 Decoupling of the circuit

Two capacitors are needed to bypass properly the TS419/TS421. A power supply bypass capacitor  $C_S$  and a bias voltage bypass capacitor  $C_B$ .

$C_S$  has particular influence on the THD+N in the high frequency region (above 7 kHz) and an indirect influence on power supply disturbances.

With 1  $\mu F$ , you can expect similar THD+N performances to those shown in the datasheet.

In the high frequency region, if  $C_S$  is lower than 1  $\mu F$ , it increases THD+N and disturbances on the power supply rail are less filtered.

On the other hand, if  $C_S$  is higher than 1  $\mu F$ , those disturbances on the power supply rail are more filtered.

$C_B$  has an influence on THD+N at lower frequencies, but its function is critical to the final result of PSRR (with input grounded and in the lower frequency region).

If  $C_B$  is lower than 1  $\mu F$ , THD+N increases at lower frequencies and PSRR worsens.

If  $C_B$  is higher than 1  $\mu F$ , the benefit on THD+N at lower frequencies is small, but the benefit to PSRR is substantial.

*Note:* *that  $C_{IN}$  has a non-negligible effect on PSRR at lower frequencies. The lower the value of  $C_{IN}$ , the higher the PSRR.*

## 5.6 Wake-up time: $T_{WU}$

When standby is released to put the device ON, the bypass capacitor  $C_B$  will not be charged immediately. As  $C_B$  is directly linked to the bias of the amplifier, the bias will not work properly until the  $C_B$  voltage is correct. The time to reach this voltage is called wake-up time or  $T_{WU}$  and typically equal to:

$T_{WU} = 0.15 \times C_B$  (s) with  $C_B$  in  $\mu F$ .

Due to process tolerances, the range of the wake-up time is:  
 $0.12 \times C_B < T_{WU} < 0.18 \times C_B$  (s) with  $C_B$  in  $\mu\text{F}$

*Note:* When the standby command is set, the time to put the device in shutdown mode is a few microseconds.

## 5.7 Pop performance

Pop performance is intimately linked with the size of the input capacitor  $C_{IN}$  and the bias voltage bypass capacitor  $C_B$ .

The size of  $C_{IN}$  is dependent on the lower cut-off frequency and PSRR values requested. The size of  $C_B$  is dependent on THD+N and PSRR values requested at lower frequencies.

Moreover,  $C_B$  determines the speed with which the amplifier turns ON. The slower the speed is, the softer the turn ON noise is.

The charge time of  $C_B$  is directly proportional to the internal generator resistance 150 k $\Omega$ .

Then, the charge time constant for  $C_B$  is

$$\tau_B = 150 \text{ k}\Omega \times C_B \text{ (s)}$$

As  $C_B$  is directly connected to the non-inverting input (pin 2 & 3) and if we want to minimize, in amplitude and duration, the output spike on  $V_{out1}$  (pin 5),  $C_{IN}$  must be charged faster than  $C_B$ . The equivalent charge time constant of  $C_{IN}$  is:

$$\tau_{IN} = (R_{in} + R_{feed}) \times C_{IN} \text{ (s)}$$

Thus we have the relation:

$$\tau_{IN} < \tau_B \text{ (s)}$$

Proper respect of this relation allows to minimize the pop noise.

Remark : Minimizing  $C_{IN}$  and  $C_B$  benefits both the pop phenomena, and the cost and size of the application.

## 5.8 Application : Differential inputs BTL power amplifier

The schematic on figure 98, shows how to design the TS419/21 to work in a differential input mode.

The gain of the amplifier is:

$$G_{VDIFF} = 2 \frac{R_2}{R_1} \quad (13)$$

In order to reach optimal performances of the differential function,  $R_1$  and  $R_2$  should be matched at 1% max.

**Figure 98. Differential input amplifier configuration**

Input capacitance  $C$  can be calculated by the following formula using the -3 dB lower frequency required. ( $F_L$  is the lower frequency required).

$$C \approx \frac{1}{2\pi R_1 F_L} \text{ (F)} \quad (14)$$

Note : This formula is true only if:

$$F_{CB} = \frac{1}{942000 \times C_B} \text{ (Hz)} \quad (15)$$

is ten times lower than  $F_L$ .

The following bill of material is an example of a differential amplifier with a gain of 2 and a -3 dB lower cutoff frequency of about 80 Hz.

Table 8. Components

Designator	Part type
R1	20 k / 1%
R2	20 k / 1%
C	100 nF
$C_B = C_S$	1 $\mu$ F
U1	TS419/21

## 6 Package information

---

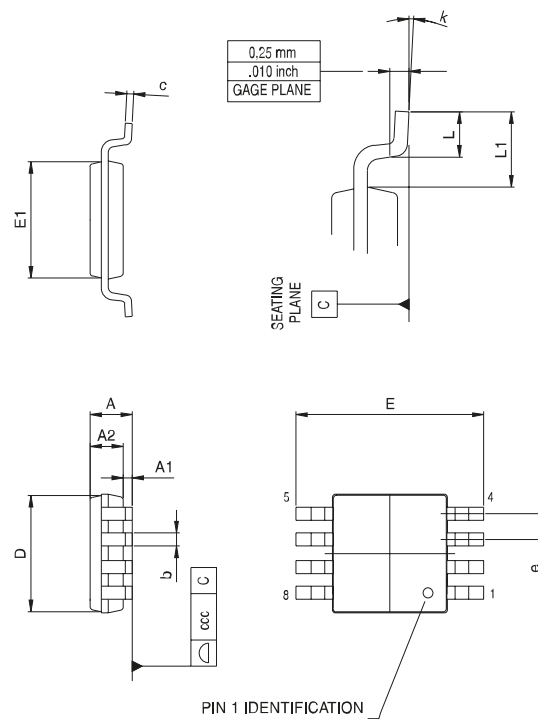
In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

## 6.1 MiniSO-8 mechanical data

Table 9. MiniSO-8 mechanical data

Dim.	mm.			inch.		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.1			0.043
A1	0.05	0.10	0.15	0.002	0.004	0.005
A2	0.78	0.86	0.94	0.031	0.031	0.037
b	0.25	0.33	0.4Q	0.010	0.13	0.013
c	0.13	0.16	0.23	0.005	0.007	0.009
D	2.90	3.00	3.10	0.114	0.118	0.122
E	4.75	4.90	5.05	0.187	0.193	0.199
E1	2.90	3.00	3.10	0.114	0.118	0.122
e		0.65			0.026	
K	0°		6°	0°		6°
L	0.40	0.55	0.70	0.016	0.022	0.028
L1			0.10			0.004

Figure 99. MiniSO-8 drawing

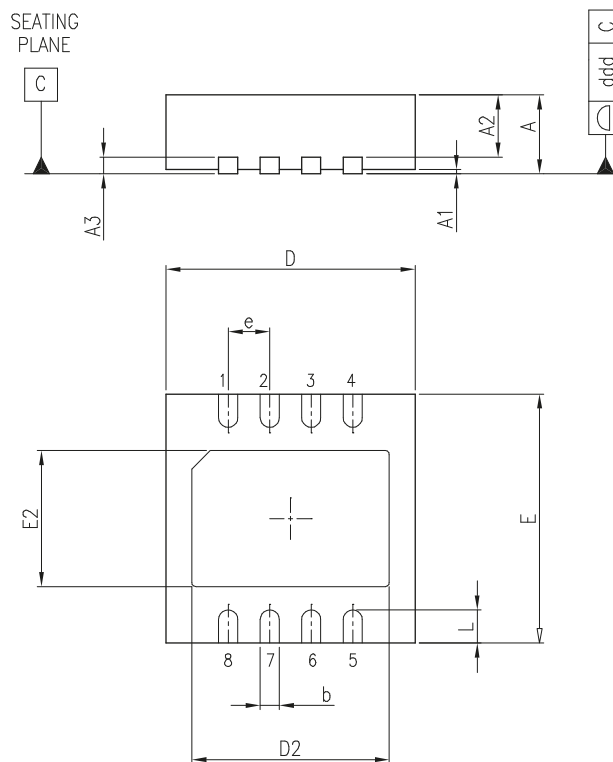


## 6.2 DFN8 (3x3) mechanical data

Table 10. DFN8 (3x3) mechanical data

Dim.	mm.			inch.		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.80	0.90	1.00	31.5	35.4	39.4
A1		0.02	0.05		0.8	2.0
A2		0.70			27.6	
A3		0.20			7.9	
b	0.18	0.23	0.30	7.1	9.1	11.8
D		3.00			118.1	
D2	2.23	2.38	2.48	87.8	93.7	97.7
E		3.00			118.1	
E2	1.49	1.64	1.74	58.7	64.6	68.5
e		0.50			19.7	
L	0.30	0.40	0.50	11.8	15.7	19.7

Figure 100. DFN8 (3x3) drawing





## 7 Ordering information

**Table 11. Order codes**

Order code	Temperature range	Package	Packing	Marking
TS419IST	-40°C to 85°C	miniSO8	Tape and reel	K19A
TS421IQT		DFN8		K21A

## Revision history

**Table 12. Document revision history**

Date	Revision	Changes
06-Feb-2013	4	No history because of migration.
29-May-2019	5	Removed the part numbers TS419IDT, TS421IDT and all its reference throughout the document.

## Contents

<b>1</b>	<b>Maximum ratings</b> .....	<b>2</b>
<b>2</b>	<b>Typical application schematics</b> .....	<b>4</b>
<b>3</b>	<b>Electrical characteristics</b> .....	<b>5</b>
<b>4</b>	<b>Electrical characteristics curves</b> .....	<b>9</b>
<b>5</b>	<b>Application information</b> .....	<b>34</b>
5.1	BTL configuration principle .....	34
5.2	Gain in typical application schematic .....	34
5.3	Low and high frequency response .....	34
5.4	Power dissipation and efficiency .....	34
5.5	Decoupling of the circuit .....	35
5.6	Wake-up time: $T_{WU}$ .....	35
5.7	Pop performance .....	36
5.8	Application : Differential inputs BTL power amplifier .....	36
<b>6</b>	<b>Package information</b> .....	<b>38</b>
6.1	MiniSO-8 mechanical data .....	39
6.2	DFN8 (3x3) mechanical data .....	39
<b>7</b>	<b>Ordering information</b> .....	<b>41</b>
	<b>Revision history</b> .....	<b>42</b>

## List of tables

<b>Table 1.</b>	Absolute maximum ratings . . . . .	2
<b>Table 2.</b>	Operating conditions . . . . .	2
<b>Table 3.</b>	Application components information . . . . .	4
<b>Table 4.</b>	Electrical characteristics $V_{CC} = +5\text{ V}$ , $GND = 0\text{ V}$ , $T_{amb} = 25\text{ }^{\circ}\text{C}$ (unless otherwise specified) . . . . .	5
<b>Table 5.</b>	Electrical characteristics $V_{CC} = +3.3\text{ V}$ , $GND = 0\text{ V}$ , $T_{amb} = 25\text{ }^{\circ}\text{C}$ (unless otherwise specified) . . . . .	6
<b>Table 6.</b>	Electrical characteristics $V_{CC} = +2.5\text{ V}$ , $GND = 0\text{ V}$ , $T_{amb} = 25\text{ }^{\circ}\text{C}$ (unless otherwise specified) . . . . .	7
<b>Table 7.</b>	Electrical characteristics $V_{CC} = +2\text{ V}$ , $GND = 0\text{ V}$ , $T_{amb} = 25\text{ }^{\circ}\text{C}$ (unless otherwise specified) . . . . .	8
<b>Table 8.</b>	Components . . . . .	37
<b>Table 9.</b>	MiniSO-8 mechanical data . . . . .	39
<b>Table 10.</b>	DFN8 (3x3) mechanical data . . . . .	40
<b>Table 11.</b>	Order codes . . . . .	41
<b>Table 12.</b>	Document revision history . . . . .	42

## List of figures

<b>Figure 1.</b>	Application schematics . . . . .	4
<b>Figure 2.</b>	Open loop gain and phase vs. frequency . . . . .	9
<b>Figure 3.</b>	Open loop gain and phase vs. frequency $V_{CC} = 2\text{ V}$ . . . . .	9
<b>Figure 4.</b>	Open loop gain and phase vs. frequency $V_{CC} = 5\text{ V}$ . . . . .	9
<b>Figure 5.</b>	Open loop gain and phase vs. frequency $Z_L = 8\ \Omega$ . . . . .	9
<b>Figure 6.</b>	Open loop gain and phase vs. frequency $R_L = 16\ \Omega$ . . . . .	10
<b>Figure 7.</b>	Open loop gain and phase vs. frequency $R_L = 16\ \Omega$ , $V_{CC} = 2\text{ V}$ . . . . .	10
<b>Figure 8.</b>	Open loop gain and phase vs. frequency $Z_L = 16\ \Omega$ , $V_{CC} = 5\text{ V}$ . . . . .	10
<b>Figure 9.</b>	Open loop gain and phase vs. frequency $Z_L = 16\ \Omega$ , $V_{CC} = 2\text{ V}$ . . . . .	10
<b>Figure 10.</b>	Open loop gain and phase vs. frequency $R_L = 32\ \Omega$ . . . . .	11
<b>Figure 11.</b>	Open loop gain and phase vs. frequency $R_L = 32\ \Omega$ , $V_{CC} = 2\text{ V}$ . . . . .	11
<b>Figure 12.</b>	Open loop gain and phase vs. frequency $Z_L = 32\ \Omega$ . . . . .	11
<b>Figure 13.</b>	Open loop gain and phase vs. frequency $Z_L = 32\ \Omega$ , $V_{CC} = 2\text{ V}$ . . . . .	11
<b>Figure 14.</b>	Current consumption vs. power supply voltage . . . . .	12
<b>Figure 15.</b>	Current consumption vs. standby voltage $V_{CC} = 5\text{ V}$ . . . . .	12
<b>Figure 16.</b>	Current consumption vs. standby voltage $V_{CC} = 3.3\text{ V}$ . . . . .	12
<b>Figure 17.</b>	Current consumption vs. standby voltage $V_{CC} = 2\text{ V}$ . . . . .	12
<b>Figure 18.</b>	Current consumption vs. standby voltage $V_{CC} = 5\text{ V}$ (TS421) . . . . .	13
<b>Figure 19.</b>	Current consumption vs. standby voltage $V_{CC} = 3.3\text{ V}$ (TS421) . . . . .	13
<b>Figure 20.</b>	Current consumption vs. standby voltage $V_{CC} = 2\text{ V}$ (TS421) . . . . .	13
<b>Figure 21.</b>	Output power vs. power supply voltage $R_L = 8\ \Omega$ . . . . .	13
<b>Figure 22.</b>	Output power vs. power supply voltage $R_L = 16\ \Omega$ . . . . .	14
<b>Figure 23.</b>	Output power vs. power supply voltage $R_L = 32\ \Omega$ . . . . .	14
<b>Figure 24.</b>	Output power vs. power supply voltage $R_L = 64\ \Omega$ . . . . .	14
<b>Figure 25.</b>	Output power vs. load resistor $V_{CC} = 5\text{ V}$ . . . . .	14
<b>Figure 26.</b>	Output power vs. load resistor $V_{CC} = 3.3\text{ V}$ . . . . .	15
<b>Figure 27.</b>	Output power vs. load resistor $V_{CC} = 2.5\text{ V}$ . . . . .	15
<b>Figure 28.</b>	Output power vs. load resistor $V_{CC} = 2\text{ V}$ . . . . .	15
<b>Figure 29.</b>	Power dissipation vs. output power $V_{CC} = 5\text{ V}$ . . . . .	15
<b>Figure 30.</b>	Power dissipation vs. output power $V_{CC} = 3.3\text{ V}$ . . . . .	16
<b>Figure 31.</b>	Power dissipation vs. output power $V_{CC} = 2.5\text{ V}$ . . . . .	16
<b>Figure 32.</b>	Power dissipation vs. output power $V_{CC} = 2\text{ V}$ . . . . .	16
<b>Figure 33.</b>	Power derating curves . . . . .	16
<b>Figure 34.</b>	Output voltage swing for one Amp. vs. power supply voltage . . . . .	17
<b>Figure 35.</b>	THD + N vs. output power $R_L = 8\ \Omega$ . . . . .	17
<b>Figure 36.</b>	THD + N vs. output power $R_L = 16\ \Omega$ . . . . .	17
<b>Figure 37.</b>	THD + N vs. output power $R_L = 32\ \Omega$ . . . . .	18
<b>Figure 38.</b>	THD + N vs. output power $R_L = 8\ \Omega$ , $A_v = 2$ . . . . .	18
<b>Figure 39.</b>	THD + N vs. output power $R_L = 16\ \Omega$ , $A_v = 2$ . . . . .	18
<b>Figure 40.</b>	THD + N vs. output power $R_L = 32\ \Omega$ , $A_v = 2$ . . . . .	18
<b>Figure 41.</b>	THD + N vs. output power $R_L = 8\ \Omega$ , $C_b = 1\ \mu\text{F}$ . . . . .	19
<b>Figure 42.</b>	THD + N vs. output power $R_L = 16\ \Omega$ , $C_b = 1\ \mu\text{F}$ . . . . .	19
<b>Figure 43.</b>	THD + N vs. output power $R_L = 32\ \Omega$ , $C_b = 1\ \mu\text{F}$ . . . . .	19
<b>Figure 44.</b>	THD + N vs. frequency $R_L = 8\ \Omega$ . . . . .	19
<b>Figure 45.</b>	THD + N vs. frequency $R_L = 16\ \Omega$ . . . . .	20
<b>Figure 46.</b>	THD + N vs. frequency $R_L = 32\ \Omega$ . . . . .	20
<b>Figure 47.</b>	Signal to noise ratio vs. power supply voltage with unweighted filter (20 Hz to 20 kHz) . . . . .	20
<b>Figure 48.</b>	Signal to noise ratio vs. power supply voltage with weighted filter Type A . . . . .	20
<b>Figure 49.</b>	Noise floor $V_{CC} = 5\text{ V}$ . . . . .	21
<b>Figure 50.</b>	Noise floor $V_{CC} = 2\text{ V}$ . . . . .	21
<b>Figure 51.</b>	PSRR vs. input capacitor . . . . .	21
<b>Figure 52.</b>	PSRR vs. power supply voltage . . . . .	21

<b>Figure 53.</b>	PSRR vs. bypass capacitor $C_b = C_{in} = 1 \mu\text{F}$ . . . . .	22
<b>Figure 54.</b>	PSRR vs. bypass capacitor $C_b = 4.7 \mu\text{F}$ . . . . .	22
<b>Figure 55.</b>	PSRR vs. bypass capacitor $C_b = 10 \mu\text{F}$ . . . . .	22
<b>Figure 56.</b>	THD + N vs. output power $R_L = 8 \Omega$ . . . . .	22
<b>Figure 57.</b>	THD + N vs. output power $R_L = 16 \Omega$ . . . . .	23
<b>Figure 58.</b>	THD + N vs. output power $R_L = 32 \Omega$ . . . . .	23
<b>Figure 59.</b>	THD + N vs. output power $R_L = 8 \Omega, A_v = 4$ . . . . .	23
<b>Figure 60.</b>	THD + N vs. output power $R_L = 16 \Omega, A_v = 4$ . . . . .	23
<b>Figure 61.</b>	THD + N vs. output power $R_L = 32 \Omega, A_v = 4$ . . . . .	24
<b>Figure 62.</b>	THD + N vs. output power $R_L = 8 \Omega$ . . . . .	24
<b>Figure 63.</b>	THD + N vs. output power $R_L = 16 \Omega$ . . . . .	24
<b>Figure 64.</b>	THD + N vs. output power $R_L = 32 \Omega$ . . . . .	24
<b>Figure 65.</b>	THD + N vs. frequency $R_L = 8 \Omega$ . . . . .	25
<b>Figure 66.</b>	THD + N vs. frequency $R_L = 16 \Omega$ . . . . .	25
<b>Figure 67.</b>	THD + N vs. frequency $R_L = 32 \Omega$ . . . . .	25
<b>Figure 68.</b>	Signal-to-noise ratio vs. power supply voltage with unweighted filter (20 Hz to 20 kHz) . . . . .	25
<b>Figure 69.</b>	Signal-to-noise ratio vs power supply voltage with weighted filter Type A . . . . .	26
<b>Figure 70.</b>	Noise floor $V_{cc} = 5 \text{ V}$ . . . . .	26
<b>Figure 71.</b>	Noise floor $V_{cc} = 2 \text{ V}$ . . . . .	26
<b>Figure 72.</b>	PSRR vs. power supply voltage . . . . .	26
<b>Figure 73.</b>	PSRR vs. input capacitor . . . . .	27
<b>Figure 74.</b>	PSRR vs. bypass capacitor $C_b = C_{in} = 1 \mu\text{F}$ . . . . .	27
<b>Figure 75.</b>	PSRR vs. bypass capacitor $C_b = C_{in} = 4.7 \mu\text{F}$ . . . . .	27
<b>Figure 76.</b>	PSRR vs. bypass capacitor $C_b = C_{in} = 10 \mu\text{F}$ . . . . .	27
<b>Figure 77.</b>	THD + N vs. output power $R_L = 8 \Omega$ . . . . .	28
<b>Figure 78.</b>	THD + N vs. output power $R_L = 16 \Omega$ . . . . .	28
<b>Figure 79.</b>	THD + N vs. output power $R_L = 32 \Omega$ . . . . .	28
<b>Figure 80.</b>	THD + N vs. output power $R_L = 8 \Omega, A_v = 8$ . . . . .	28
<b>Figure 81.</b>	THD + N vs. output power $R_L = 16 \Omega, A_v = 8$ . . . . .	29
<b>Figure 82.</b>	THD + N vs. output power $R_L = 32 \Omega, A_v = 8$ . . . . .	29
<b>Figure 83.</b>	THD + N vs. output power $R_L = 8 \Omega, C_b = 1 \mu\text{F}$ . . . . .	29
<b>Figure 84.</b>	THD + N vs. output power $R_L = 16 \Omega, C_b = 1 \mu\text{F}$ . . . . .	29
<b>Figure 85.</b>	THD + N vs. output power $R_L = 32 \Omega, C_b = 1 \mu\text{F}$ . . . . .	30
<b>Figure 86.</b>	THD + N vs. frequency $R_L = 8 \Omega$ . . . . .	30
<b>Figure 87.</b>	THD + N vs. frequency $R_L = 16 \Omega$ . . . . .	30
<b>Figure 88.</b>	THD + N vs. frequency $R_L = 32 \Omega$ . . . . .	30
<b>Figure 89.</b>	Signal to noise ratio vs. power supply voltage with unweighted filter (20 Hz to 20 kHz) . . . . .	31
<b>Figure 90.</b>	Signal to noise ratio vs. power supply voltage with weighted filter Type A . . . . .	31
<b>Figure 91.</b>	Noise floor $V_{cc} = 5 \text{ V}$ . . . . .	31
<b>Figure 92.</b>	Noise floor $V_{cc} = 2 \text{ V}$ . . . . .	31
<b>Figure 93.</b>	PSRR vs. power supply voltage . . . . .	32
<b>Figure 94.</b>	PSRR vs. input capacitor . . . . .	32
<b>Figure 95.</b>	PSRR vs. bypass capacitor $C_b = C_{in} = 1 \mu\text{F}$ . . . . .	32
<b>Figure 96.</b>	PSRR vs. bypass capacitor $C_b = 4.7 \mu\text{F}$ . . . . .	32
<b>Figure 97.</b>	PSRR vs. bypass capacitor $C_b = 1 \mu\text{F}$ . . . . .	33
<b>Figure 98.</b>	Differential input amplifier configuration . . . . .	36
<b>Figure 99.</b>	MiniSO-8 drawing . . . . .	39
<b>Figure 100.</b>	DFN8 (3x3) drawing . . . . .	40

**IMPORTANT NOTICE – PLEASE READ CAREFULLY**

STMicroelectronics NV and its subsidiaries (“ST”) reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST’s terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers’ products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. For additional information about ST trademarks, please refer to [www.st.com/trademarks](http://www.st.com/trademarks). All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2019 STMicroelectronics – All rights reserved



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

**Телефон:** 8 (812) 309 58 32 (многоканальный)

**Факс:** 8 (812) 320-02-42

**Электронная почта:** [org@eplast1.ru](mailto:org@eplast1.ru)

**Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.